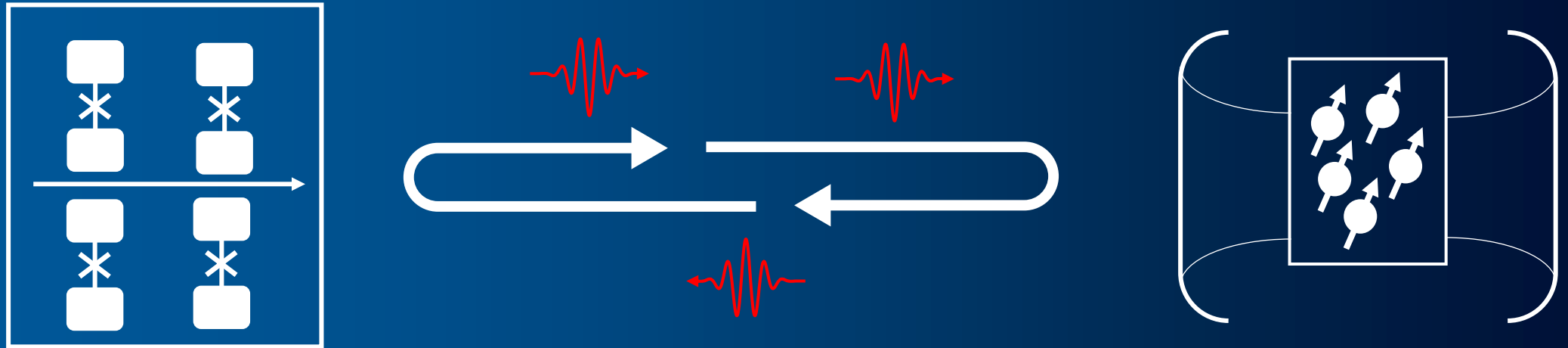


Quantum memory with electronic spins

Audrey Bienfait



Classical versus quantum memory

Store a bit



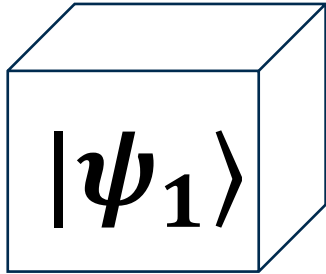
Metrics

Latency/bandwidth

Coherence & Lifetime & error rate

Capacity

Store a qubit

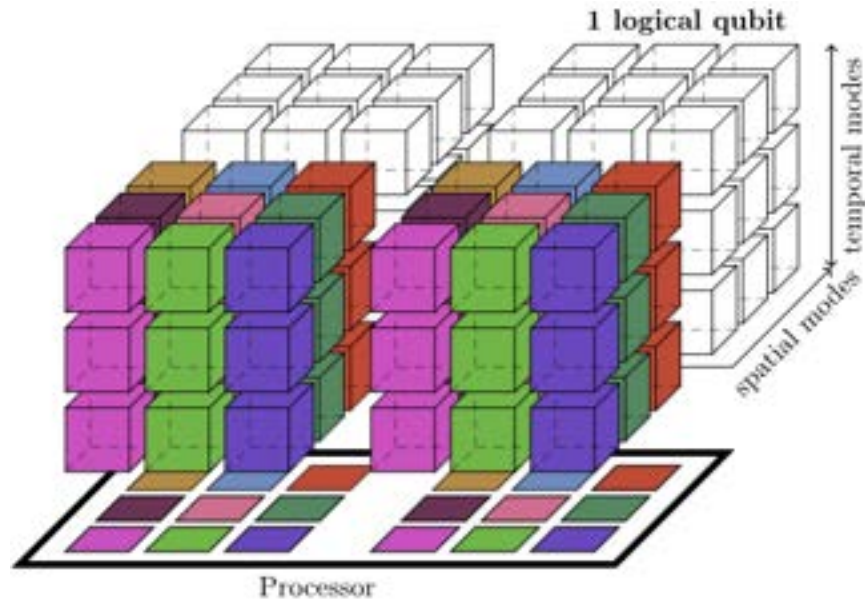


(quantum) random-access memory

(Power consumption)

Why store quantum states ?

Reduce the number of processing qubits in a quantum computer



Factoring 2048-bit RSA Integers in 177 Days with 13 436 Qubits and a Multimode Memory, Gouzien & Sangouard, *PRL* (2021)

Quantum memory hierarchies: Efficient designs to match available parallelism in quantum computing, Thaker et al., Symposium on Computer Architecture (2006).

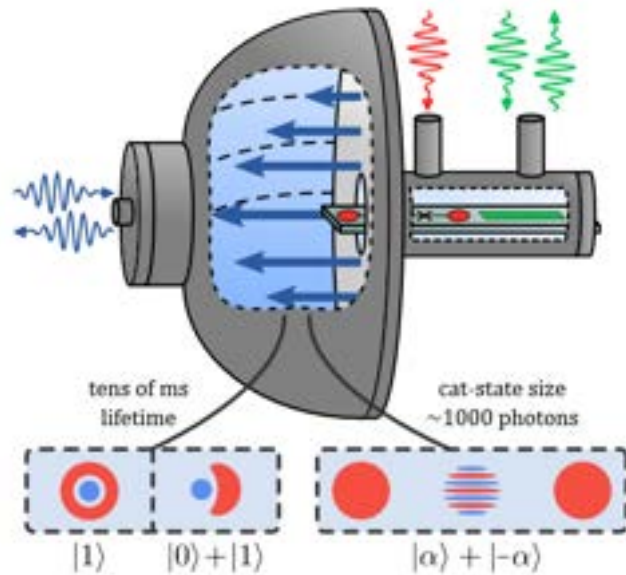
Enable long-distance communication



The quantum internet, H. J. Kimble, *Nature* (2008)

Platforms for storing microwave quantum states ?

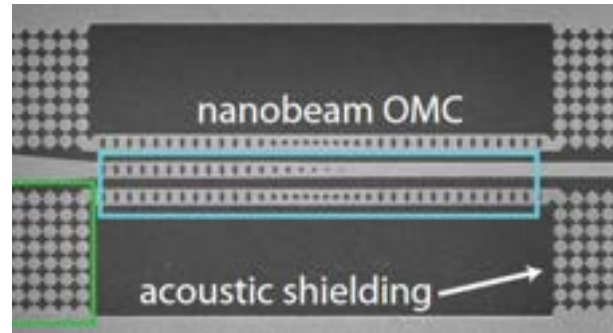
Superconducting cavities



$$\begin{aligned} T_1 &= 110 \text{ ms} \\ T_2 &= 34 \text{ ms} \\ T_{\text{swap}} &\sim 1 \text{ } \mu\text{s} \end{aligned}$$

Millul et al., *PRX Quantum* (2023)

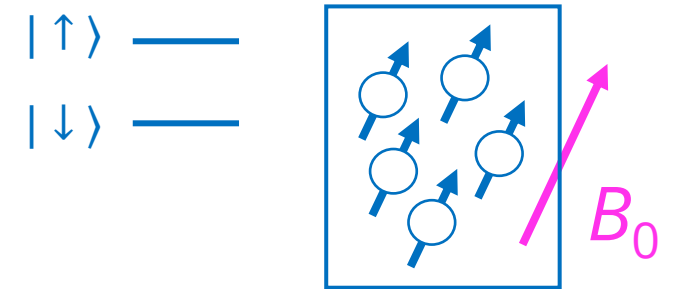
Mechanical devices



$$\begin{aligned} T_1 &= 1.5 \text{ s} \\ T_2 &= 130 \text{ } \mu\text{s} \\ T_{\text{swap}} &\sim 1 \text{ } \mu\text{s} \end{aligned}$$

MacCabe et al., *Science* (2020)

Defect spins in crystals

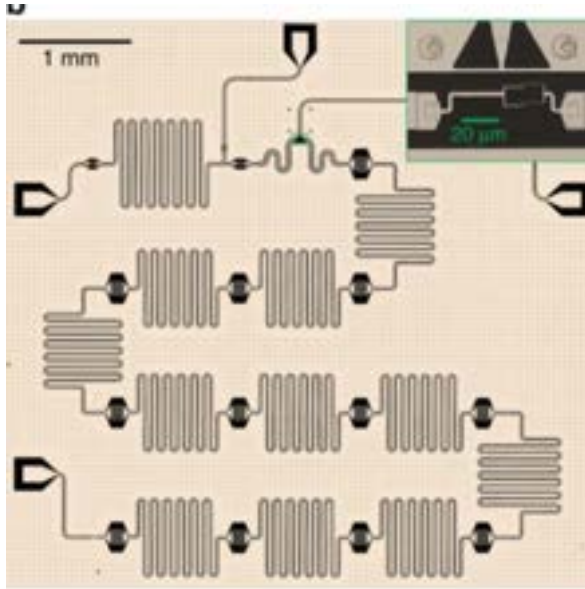


$$\begin{aligned} T_1 &> 10 \text{ s}, \\ T_2 &= 2.9 \text{ s @clock transitions} \\ T_{\text{swap}} &\sim 10 \text{ } \mu\text{s} \end{aligned}$$

Wolfowicz et al.,
Nature nano (2013)

Multimodal ?

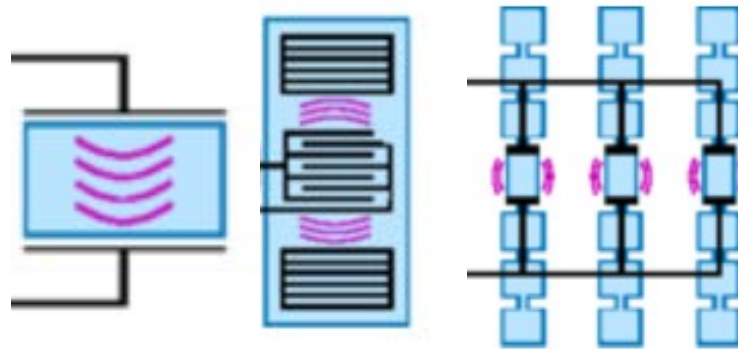
Superconducting cavities



$$N_{\text{modes}} = 10$$

Naik et al., *Nat. Comm.* (2017)

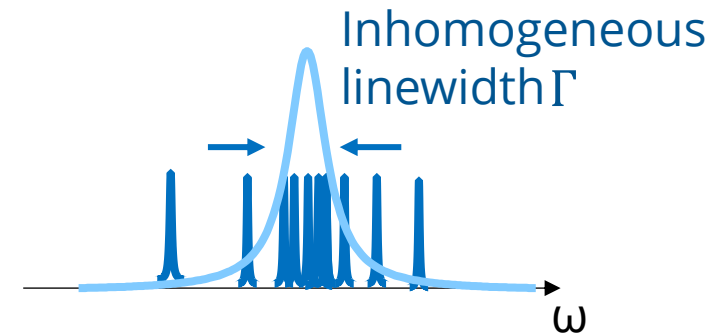
Mechanical devices



$$N_{\text{modes}} = 10 \text{ to } 100$$

Hahn et al., *PRL* (2019)

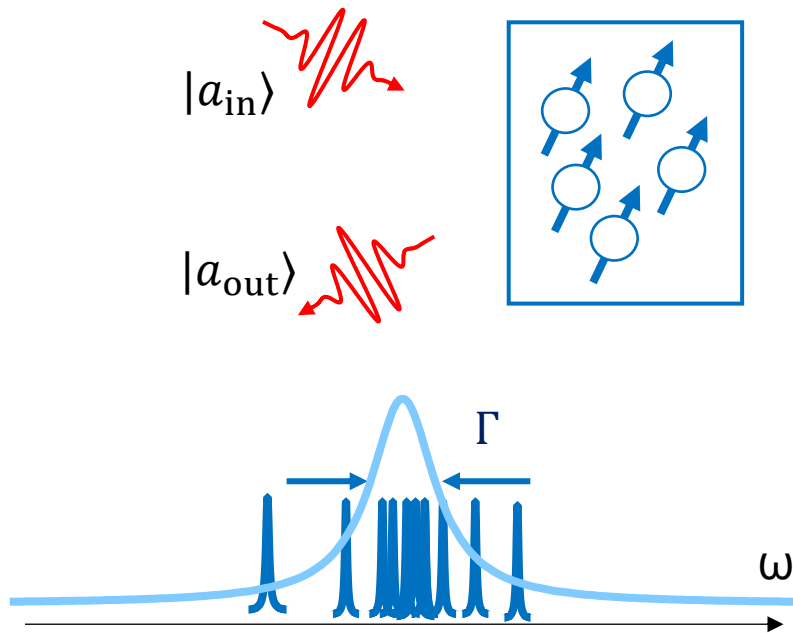
Defect spins in crystals



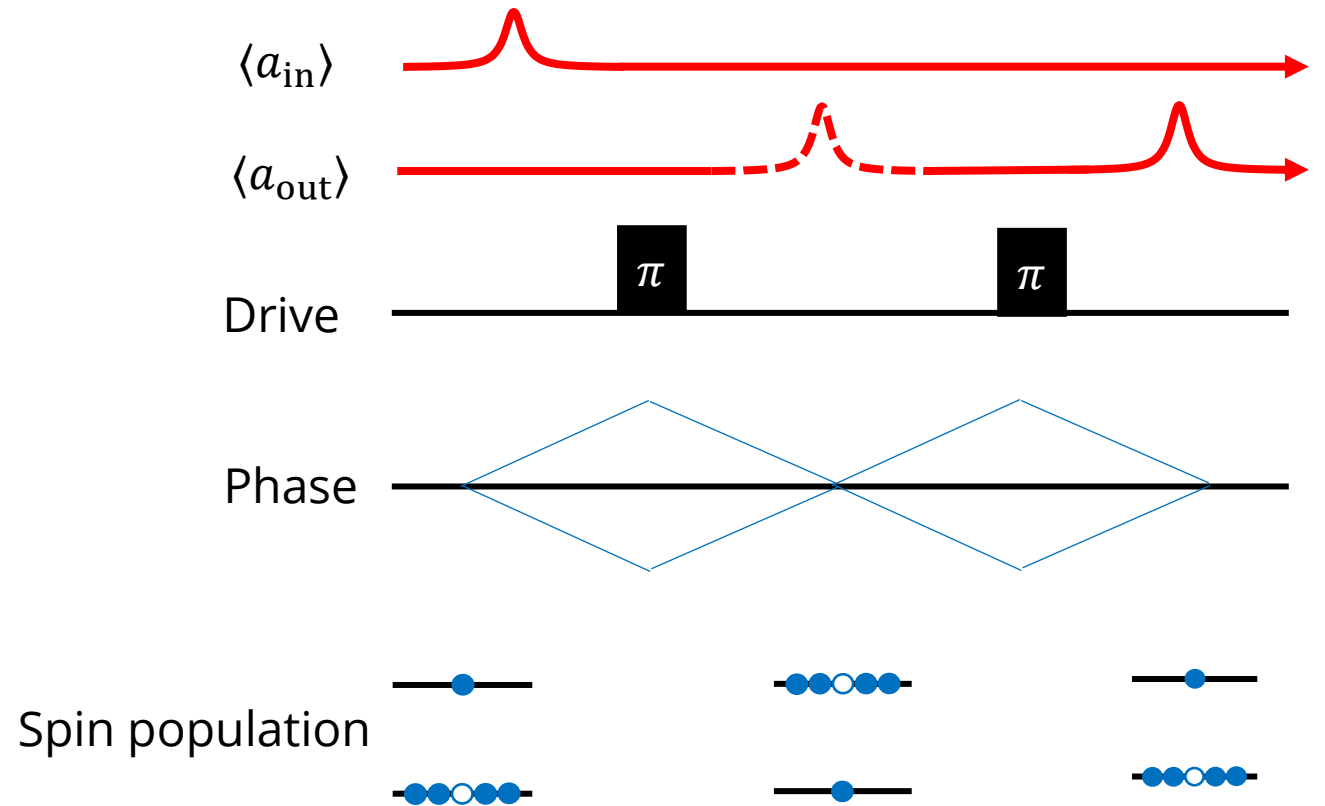
$$N_{\text{modes}} = N_{\text{spins}} ?$$

Echo-based quantum memory

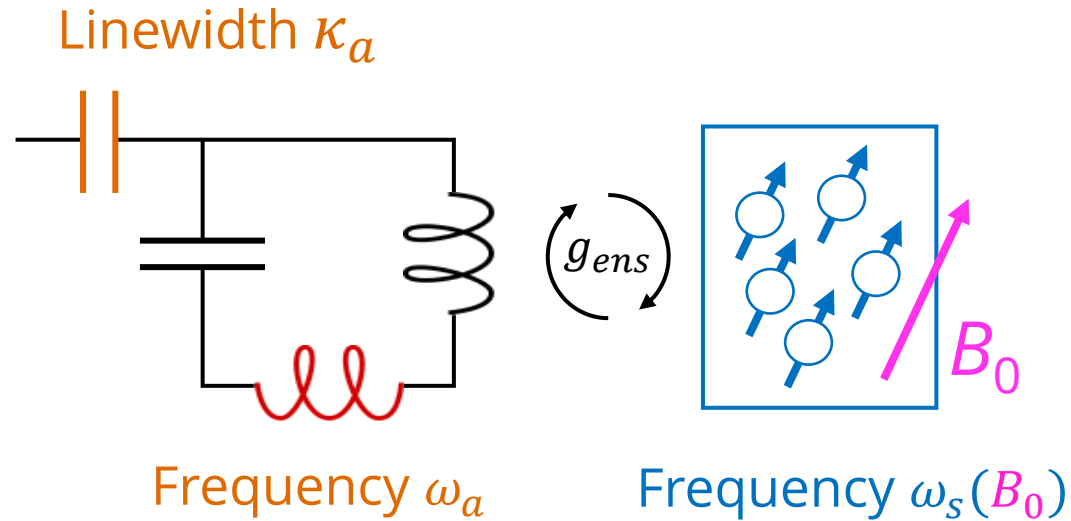
Ensemble of spins,
with some inhomogeneous broadening



Recovery of silenced echo (ROSE) protocols



Spin ensemble coupled to a superconducting resonator

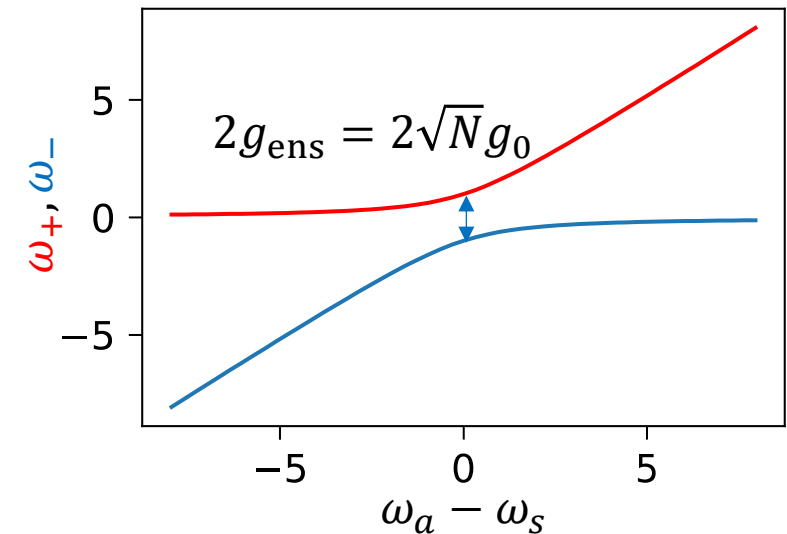


$$H = \mu (\vec{B}_0 + \vec{B}_1) \cdot \vec{S}$$

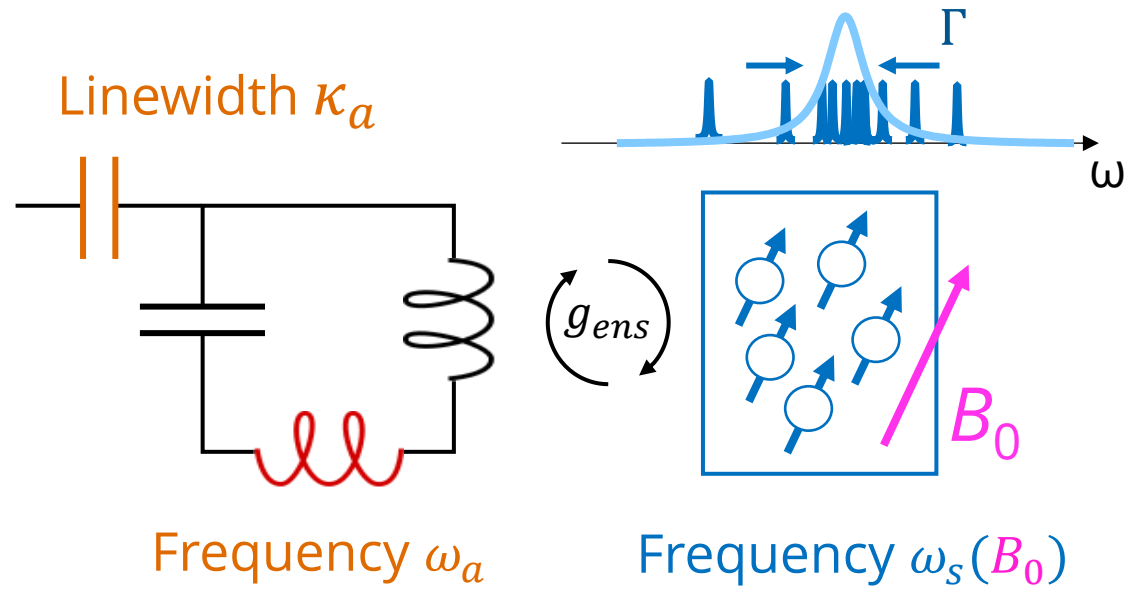
$$H_{\text{int}} = \underbrace{\mu \delta B_1}_{\text{Coupling constant to spin } \frac{1}{2}} (a + a^\dagger)(\sigma_+ + \sigma_-)$$

Coupling constant to spin $\frac{1}{2}$

$$\frac{g_0}{2\pi} = 1 \text{ mHz} - 5 \text{ kHz}$$

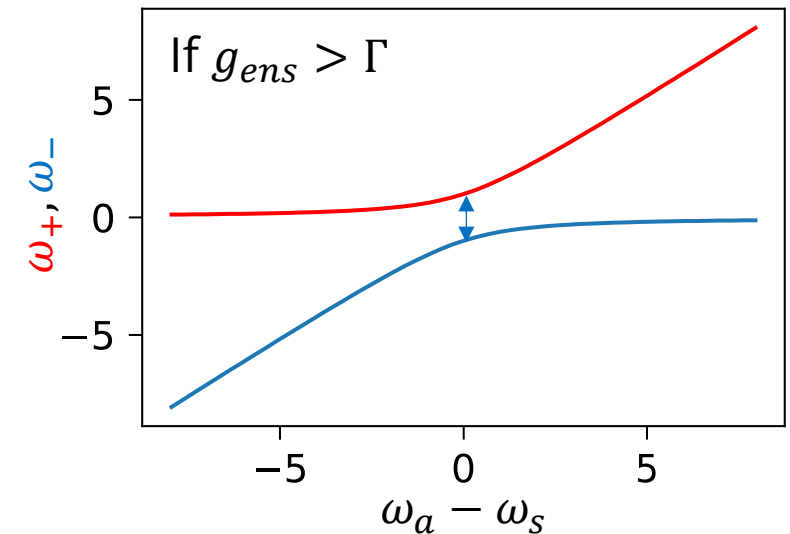


Spin ensemble coupled to a superconducting resonator

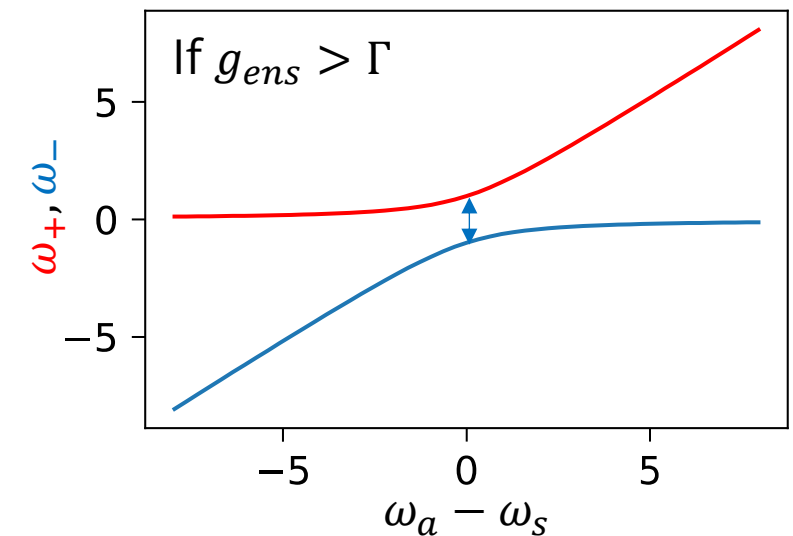
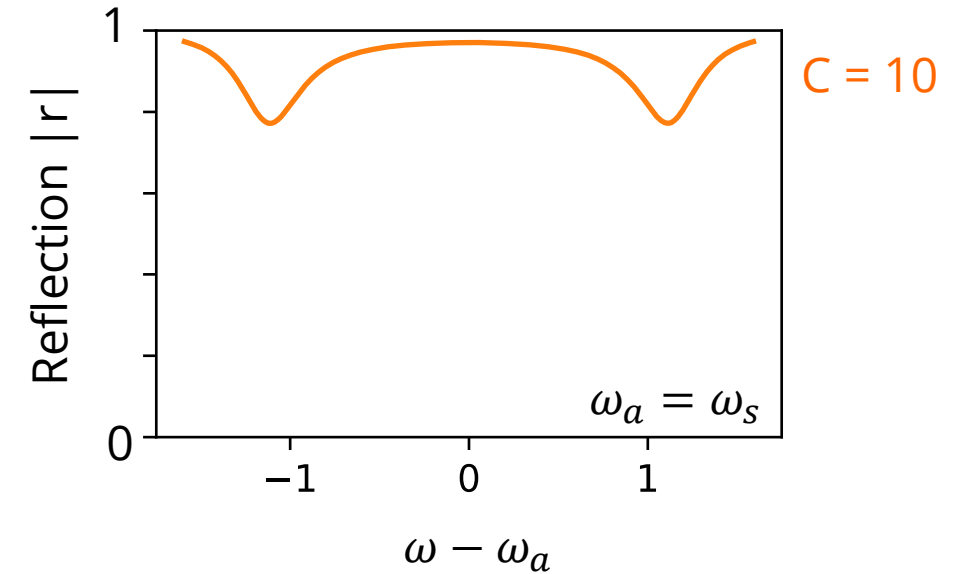
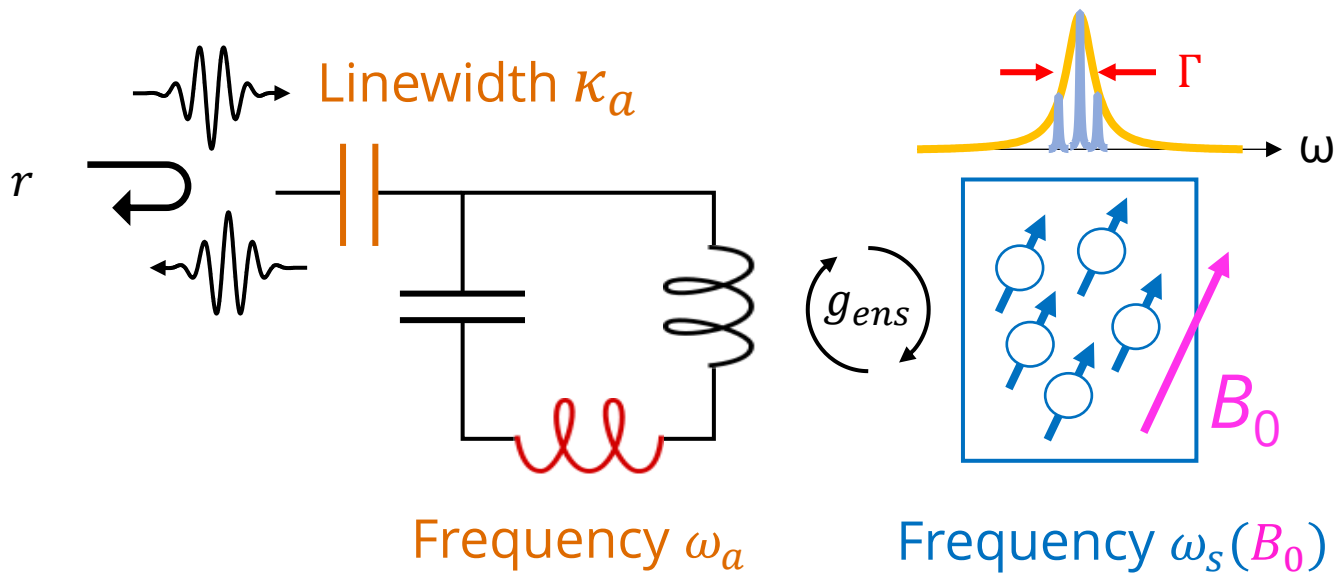


Regime of interaction given by cooperativity

$$C = \frac{4 g_{ens}^2}{\kappa_a \Gamma} = \frac{4 N g_0^2}{\kappa_a \Gamma}$$



Spin ensemble coupled to a superconducting resonator

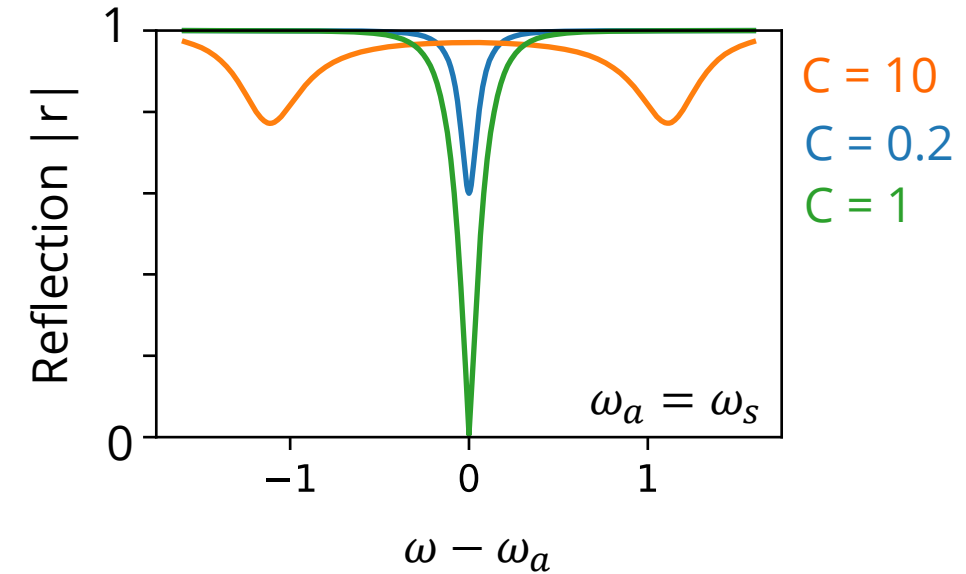
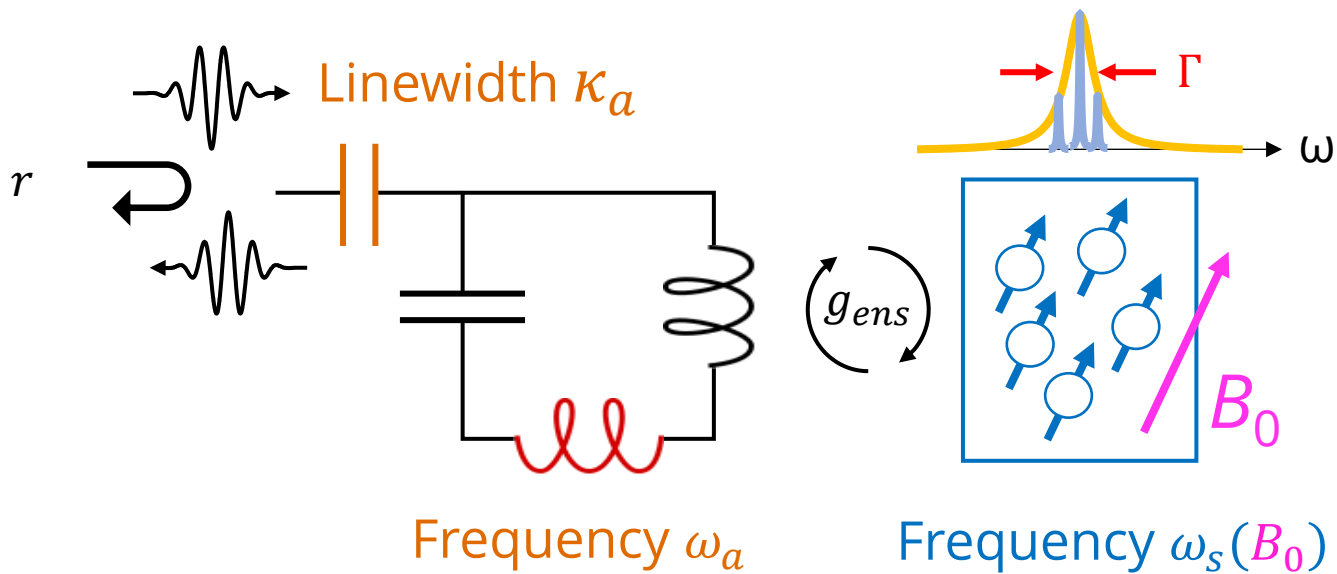


High cooperativity

Signature of avoided level crossings

Coherent swaps between resonators and spins, with exchange time limited by $1/\Gamma$

Spin ensemble coupled to a superconducting resonator



High cooperativity

Signature of avoided level crossings

Coherent swaps between resonators and spins, with exchange time limited by $1/\Gamma$

Unit cooperativity

Perfect absorption into the spins, with bandwidth $\kappa_s = \frac{4g_{ens}^2}{\Gamma}$

No coherent swapping

Low cooperativity

Spins act as a loss channel with decay rate $\kappa_s = \frac{4g_{ens}^2}{\Gamma}$

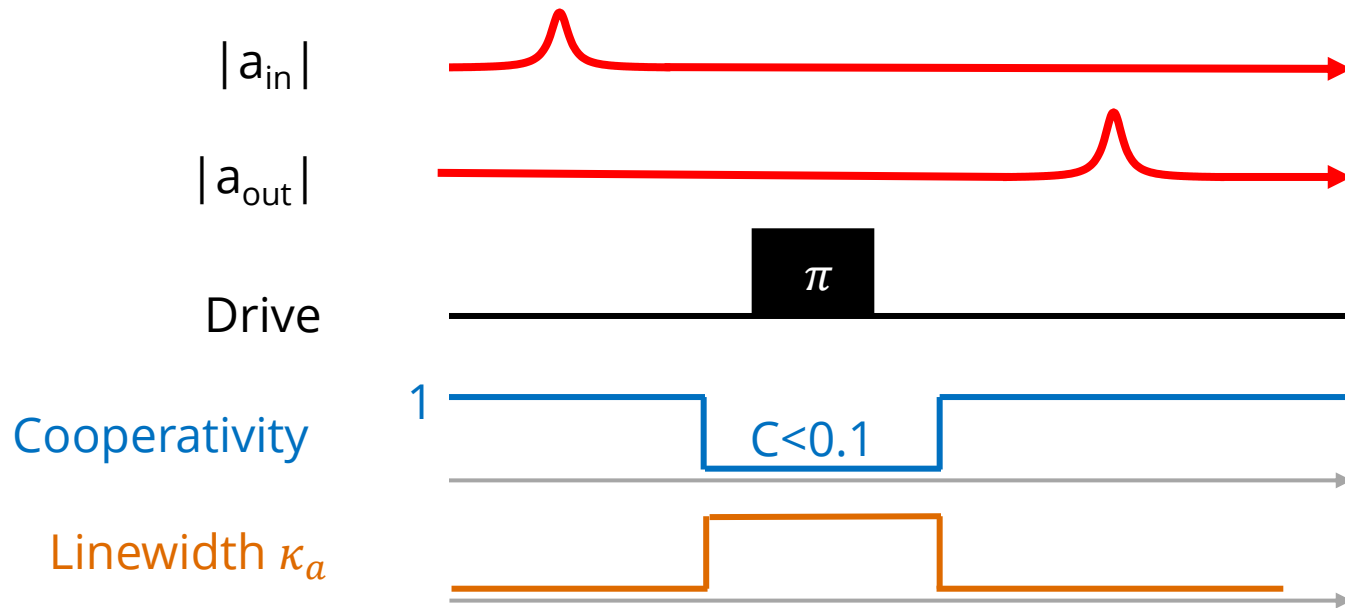
No coherent swapping

Possible to drive the spins classically

Spins can deexcite via the resonator (Purcell effect)

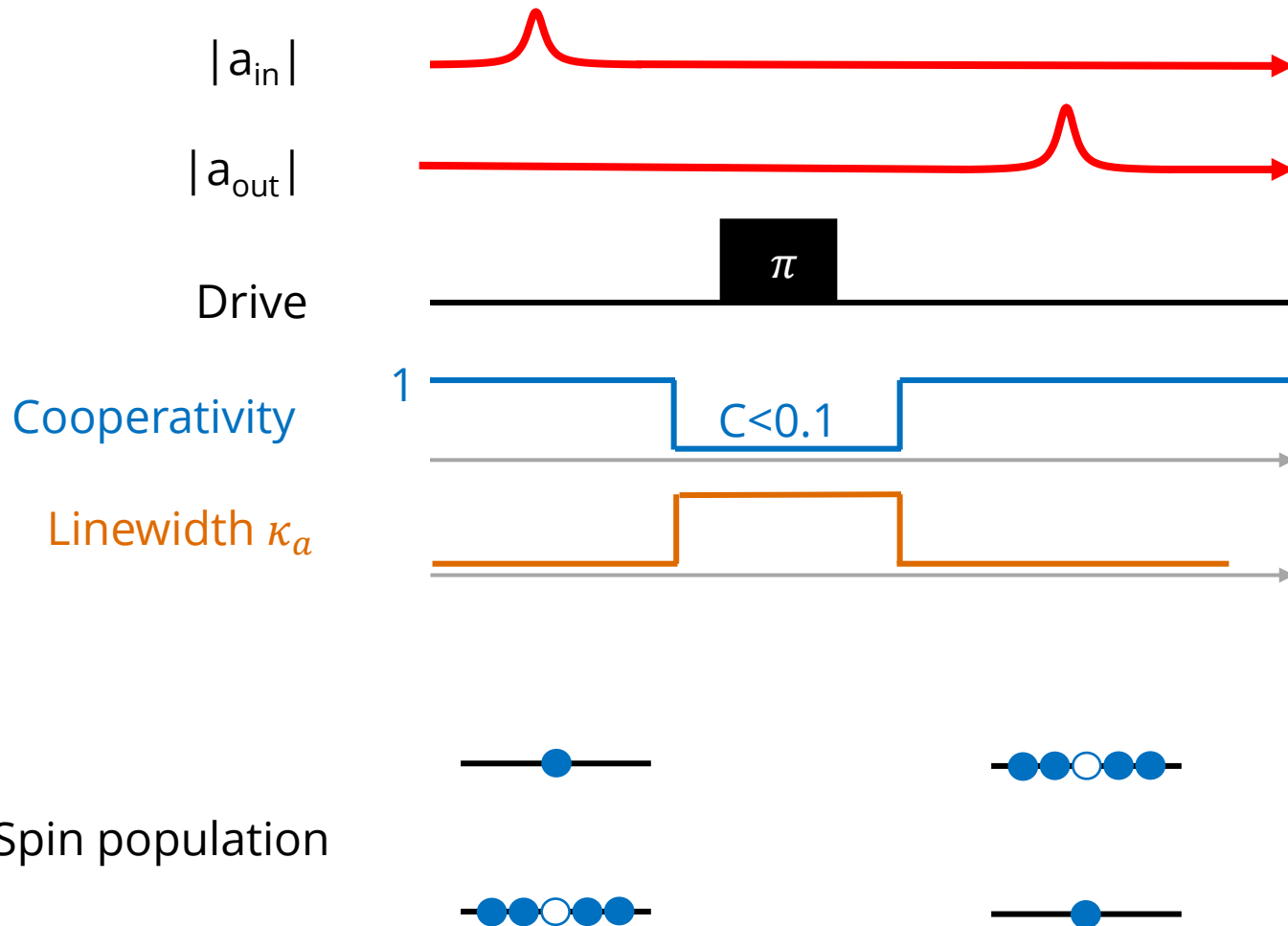
Spin ensemble as a memory: protocol

How to store an incoming arbitrary wave packet and retrieve it?



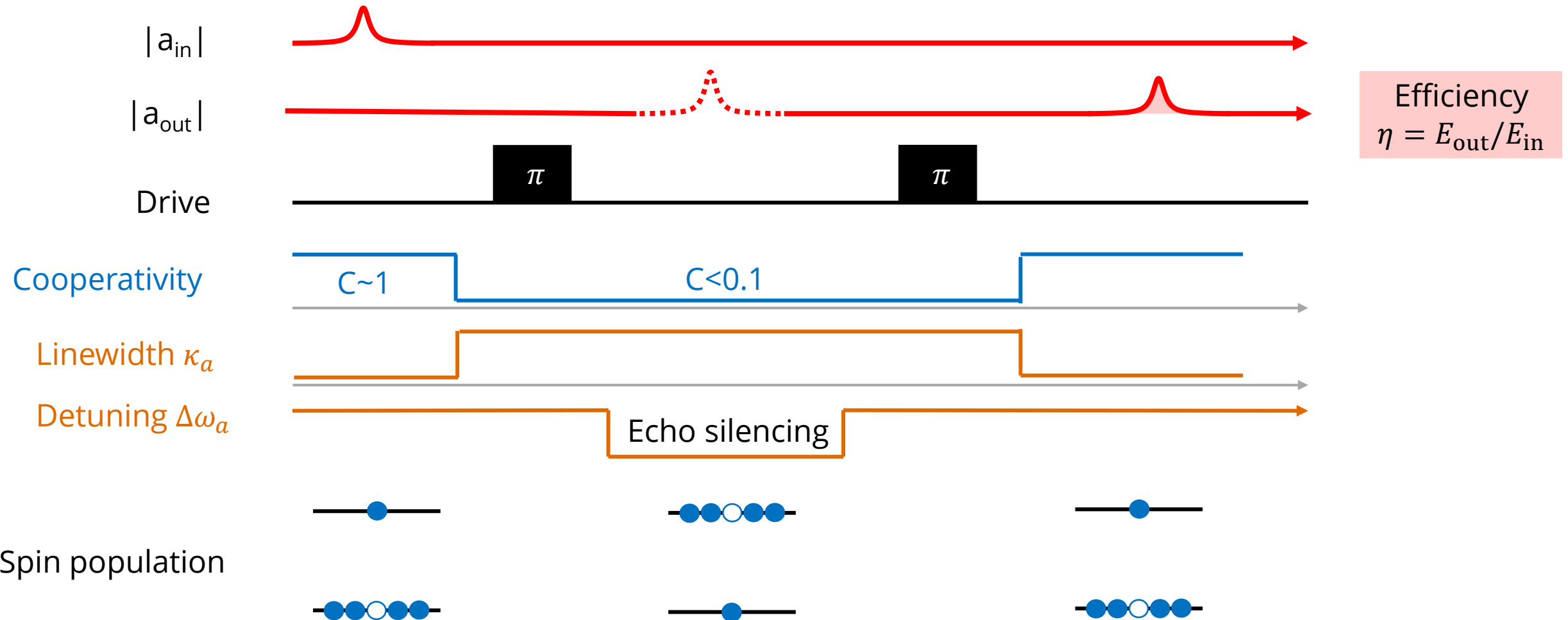
Spin ensemble as a memory: protocol

How to store an incoming arbitrary wave packet and retrieve it?



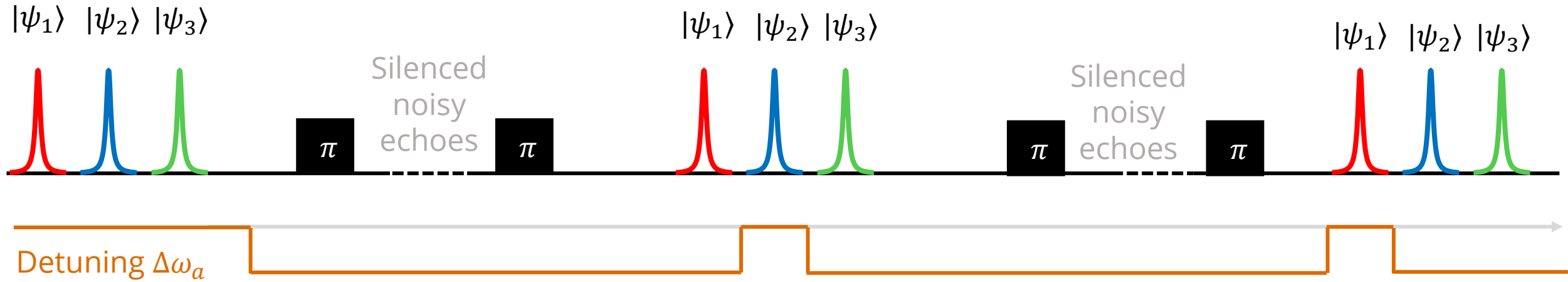
Spin ensemble as a memory: protocol

How to store an incoming arbitrary wave packet and retrieve it?



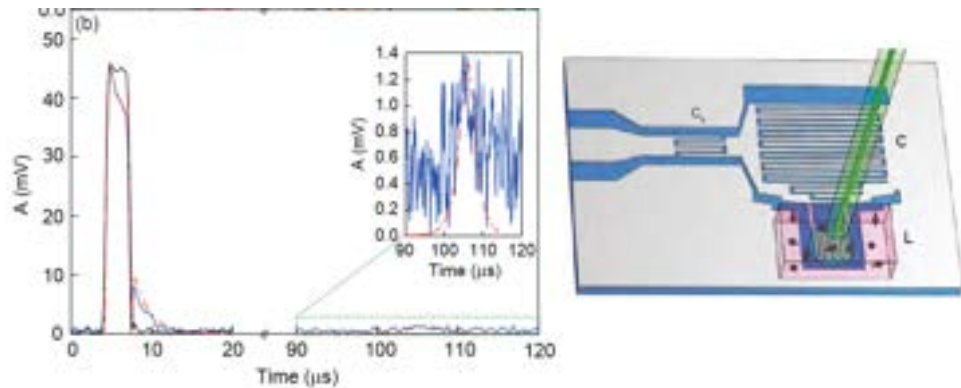
Multimode?

Random access to multiple stored states by echo silencing... except on retrieval !



Spin-ensemble as a memory : state of the art

NV centers in diamond



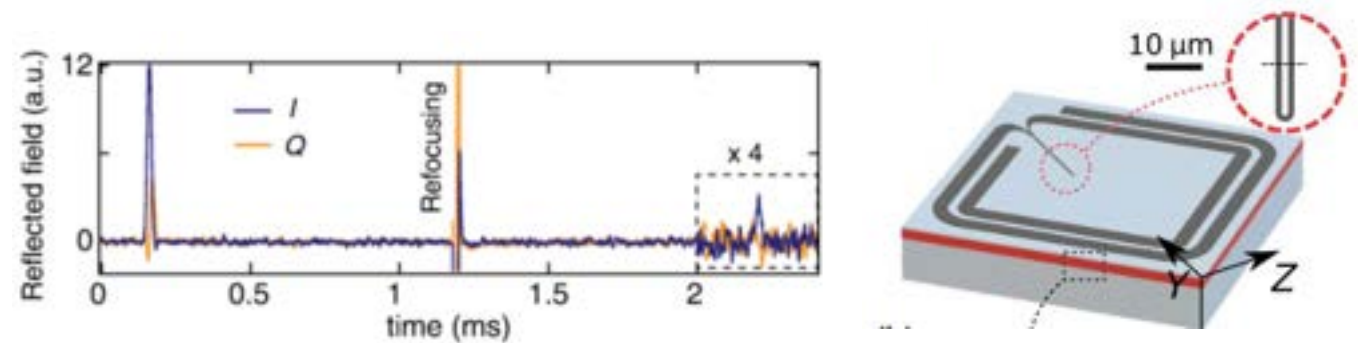
Grezes et al., *PRA* (2015)

Efficiency 0.3 %

$C = 0.22$

$T_2 = 84 \mu\text{s}$

Bismuth donors in silicon



Ranjan et al., *PRL* (2020)

Efficiency 0.1 %

$C = 0.04$

$T_2 = 0.3 \text{ s}$

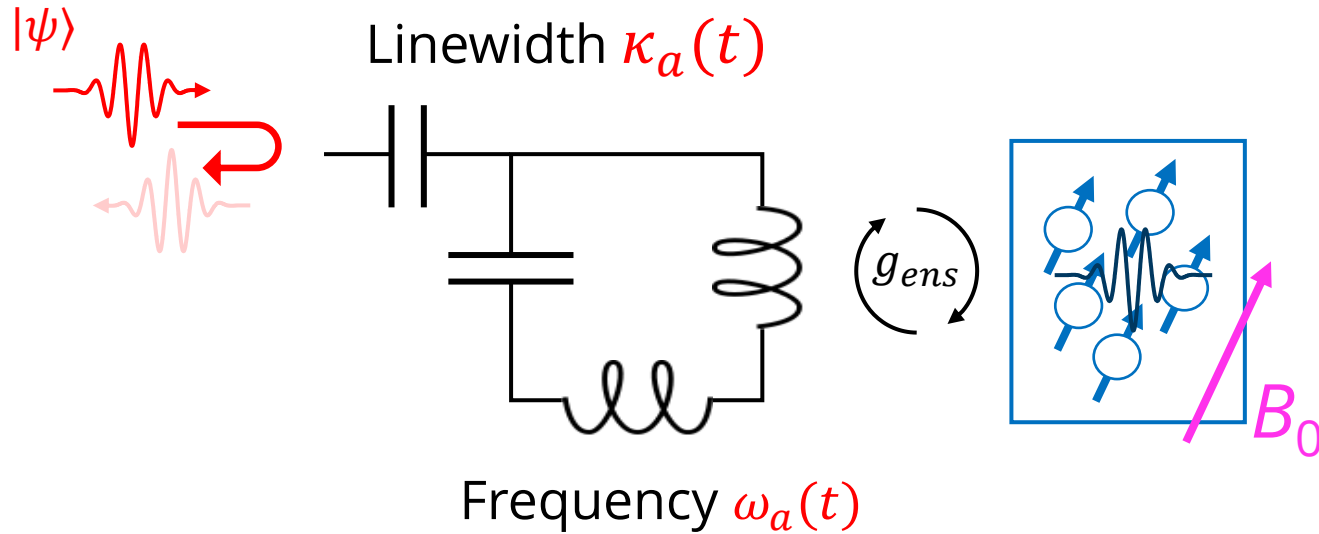
O'Sullivan et al., *PRX* (2022)

Efficiency 3 %

$C = 0.06$

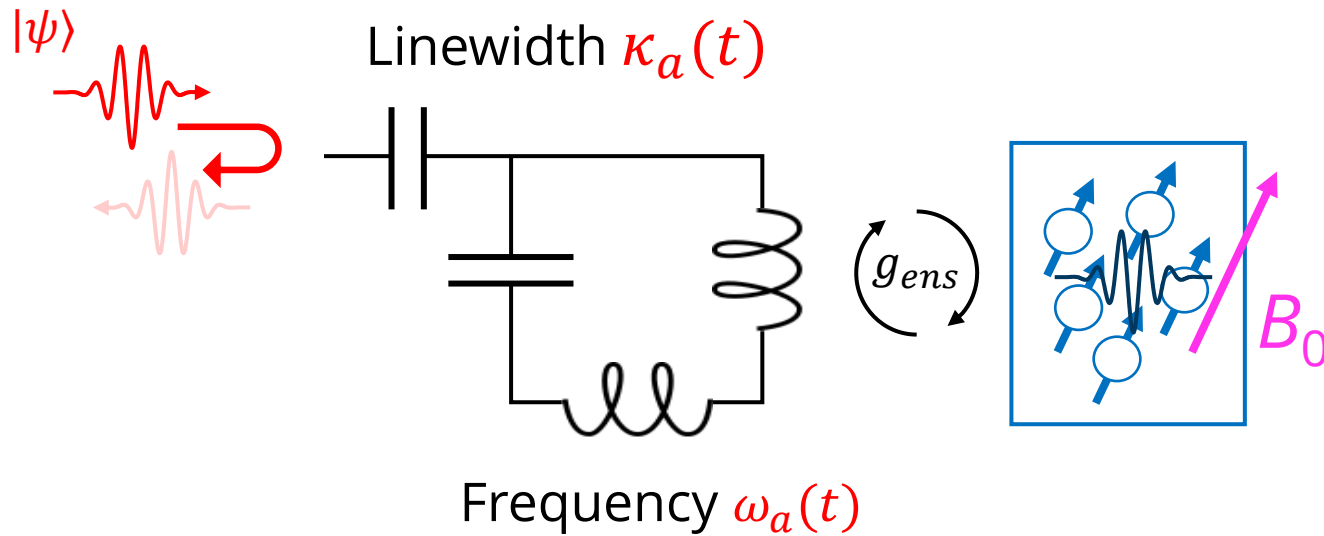
$T_2 = 2 \text{ ms}$

Quantum memory requirements

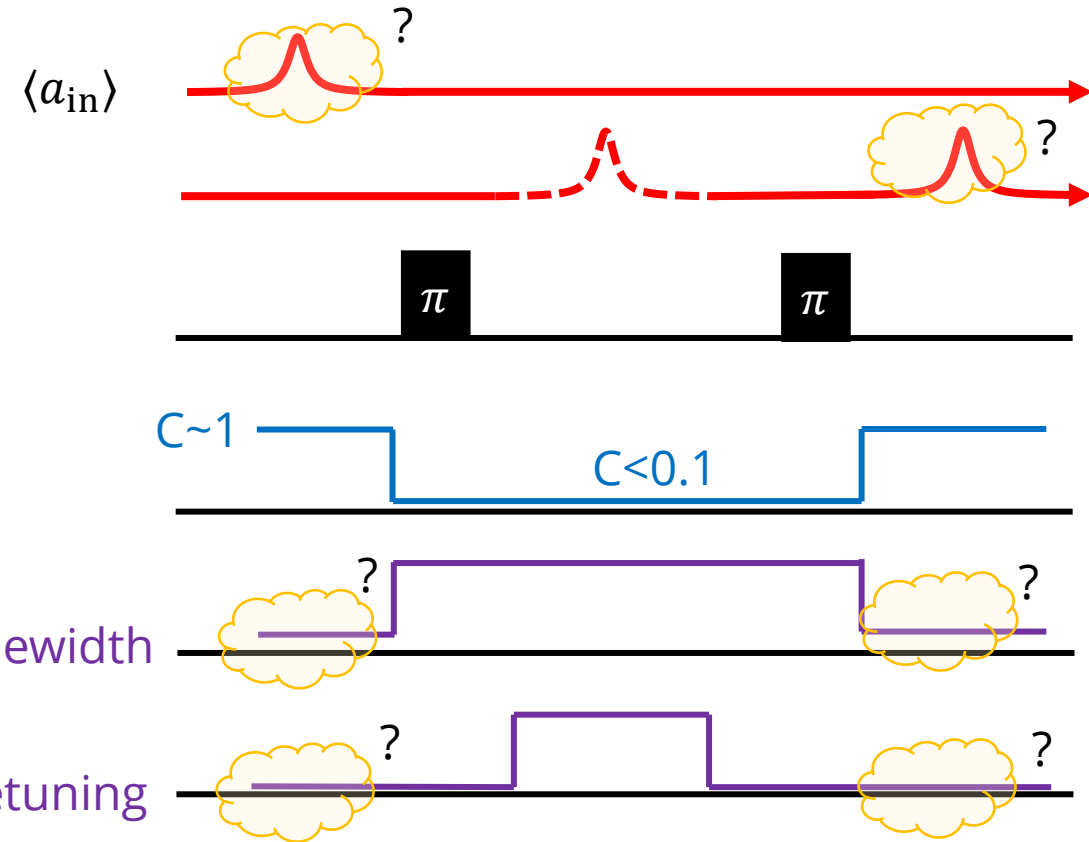


- ☐ Long spin coherence
 - Aim for clock transitions
- ☐ Reach unit cooperativity
- ☐ **Tunable** resonator frequency
 - ☐ For echo silencing
 - ☐ For aiming at clock transitions
- ☐ **Tunable** linewidth
 - ☐ For cooperativity tuning
 - ☐ For perfect absorption ?

Quantum memory requirements



- Can we absorb faster than at rate κ_s ?
- What **control fields** for best efficiency ?
 - Input field
 - Linewidth modulation
 - Detuning



Quantum state transfers, etc...
A. N. Korotkov, *PRB* (2011) + many others...



Linda
Gregg



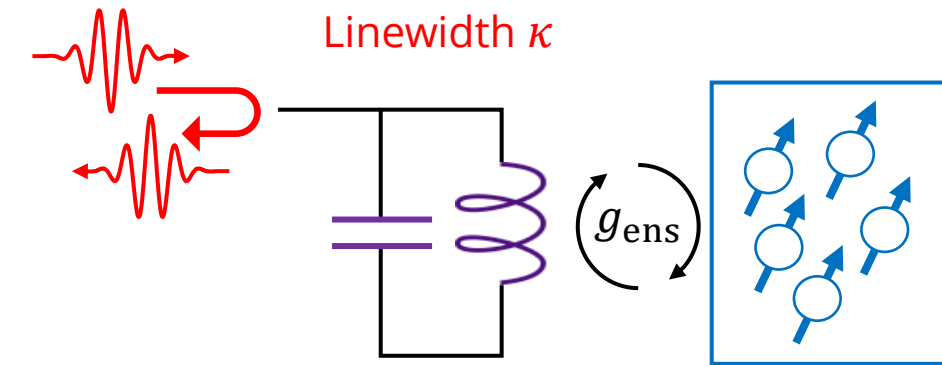
Alexandru
Petrescu



Mazyar
Mirrahimi

Modeling absorption

Detuning δ



Detuning δ_r

Cavity operator a Spin lowering operator σ_-

Assuming a Lorentzian spin frequency distribution

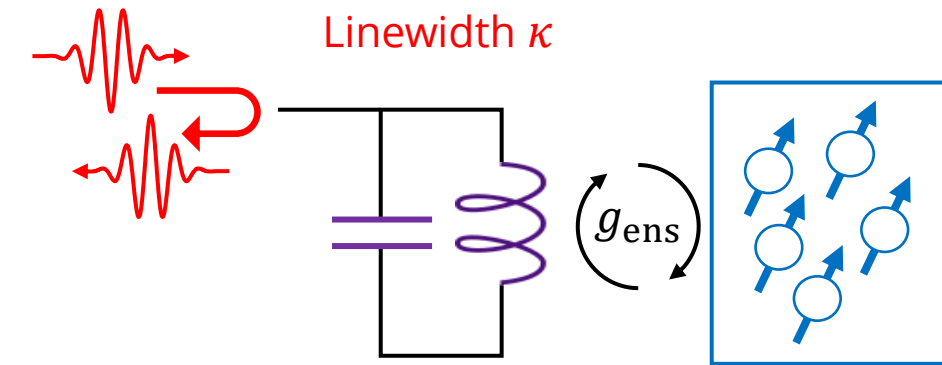
Equations of motion : **control fields**

$$\frac{d}{dt} a = -\frac{\kappa_0 + \kappa(t) - 2i \delta_r(t)}{2} a + i \sum_j g_j \sigma_-^j + \sqrt{\kappa(t)} a_{\text{in}}(t)$$

$$\frac{d}{dt} \sigma_-^j = -i \delta_j \sigma_-^j + i g_j a$$

Modeling absorption

Detuning δ



Detuning δ_r

Cavity operator a Spin lowering operator σ_-

Equations of motion : **control fields**

$$\frac{d}{dt} a = -\frac{\kappa_0 + \kappa(t) - 2i \delta_r(t)}{2} a + i \sum_j g_j \sigma_-^j + \sqrt{\kappa(t)} a_{\text{in}}(t)$$

$$\frac{d}{dt} \sigma_-^j = -i \delta_j \sigma_-^j + i g_j a$$

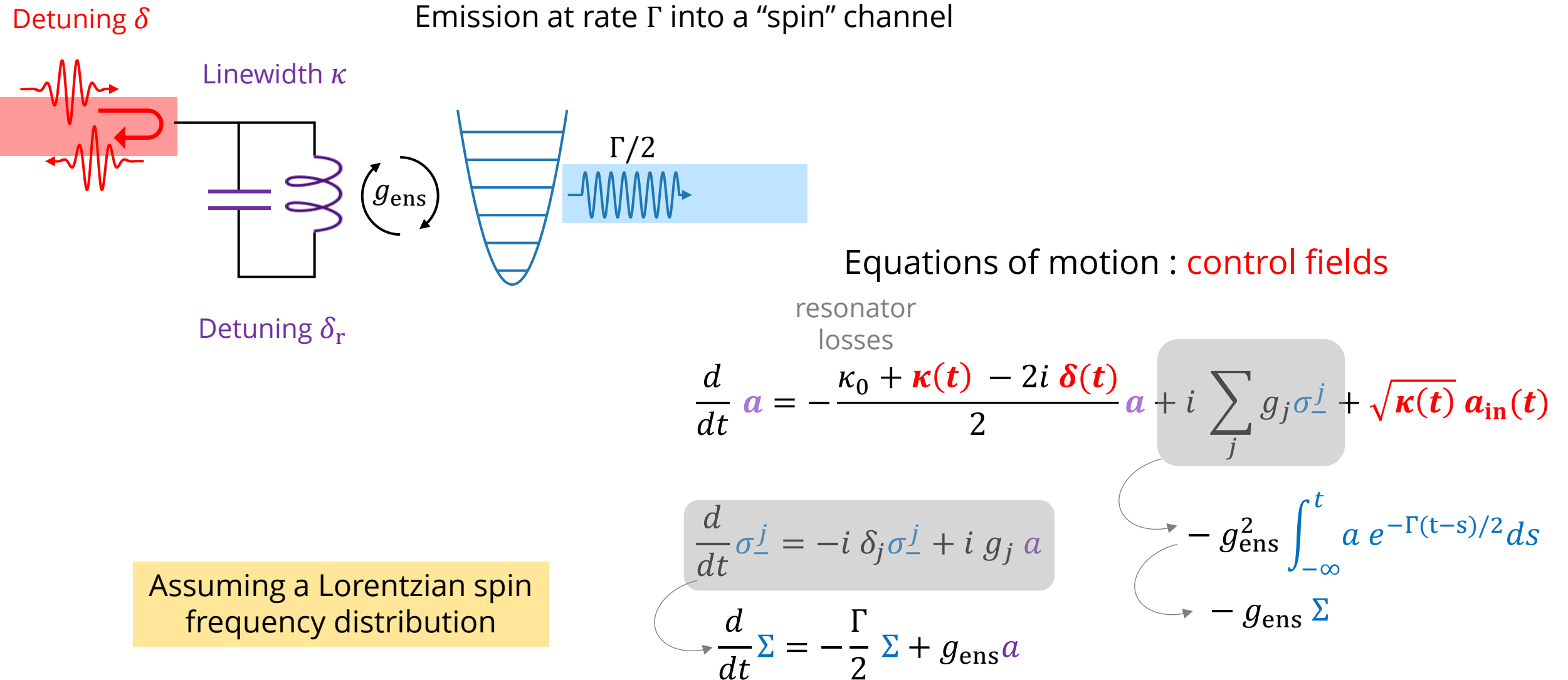
$$\frac{d}{dt} \Sigma = -\Gamma \Sigma + g_{\text{ens}} a$$

Assuming a Lorentzian spin frequency distribution

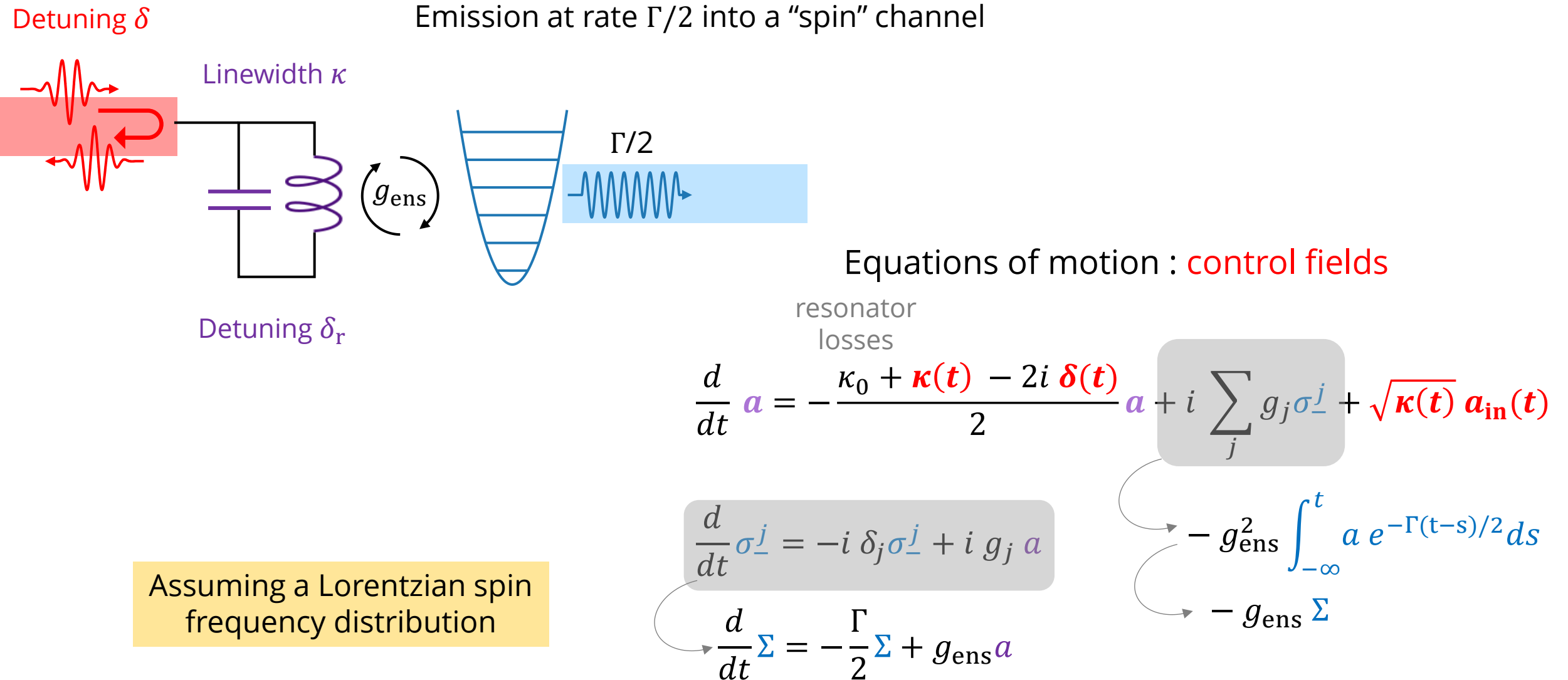
$$-g_{\text{ens}}^2 \int_{-\infty}^t a e^{-\Gamma(t-s)/2} ds$$

$$-g_{\text{ens}} \Sigma$$

Modeling absorption

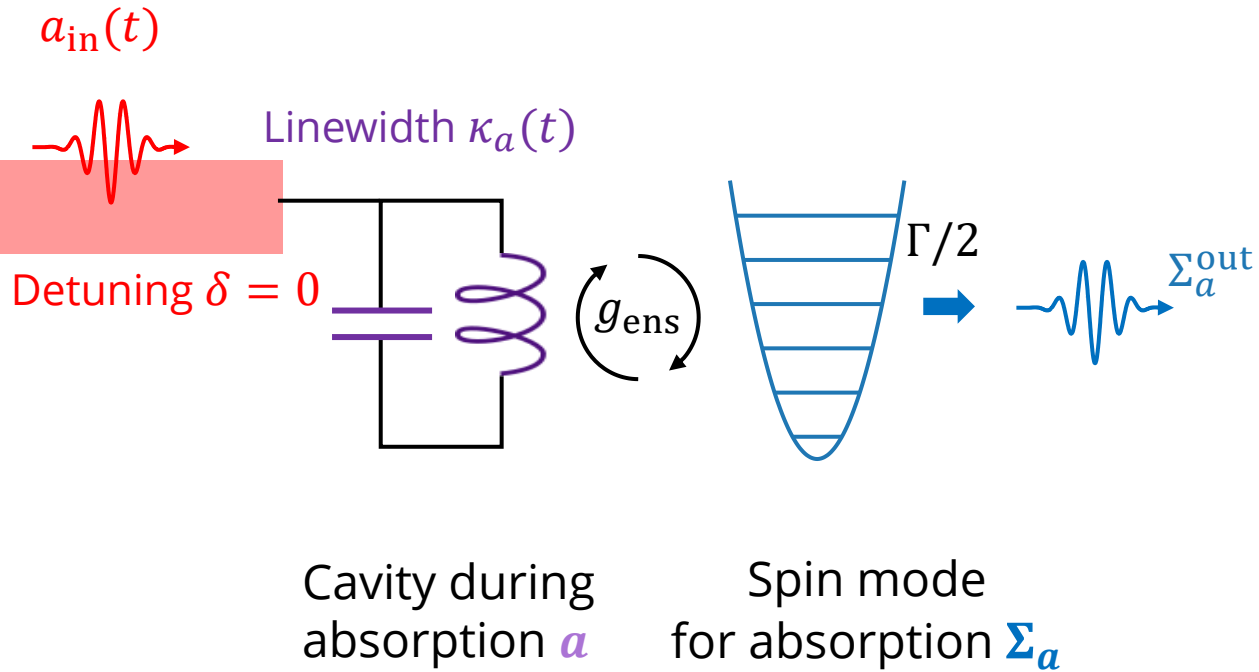


Modeling absorption



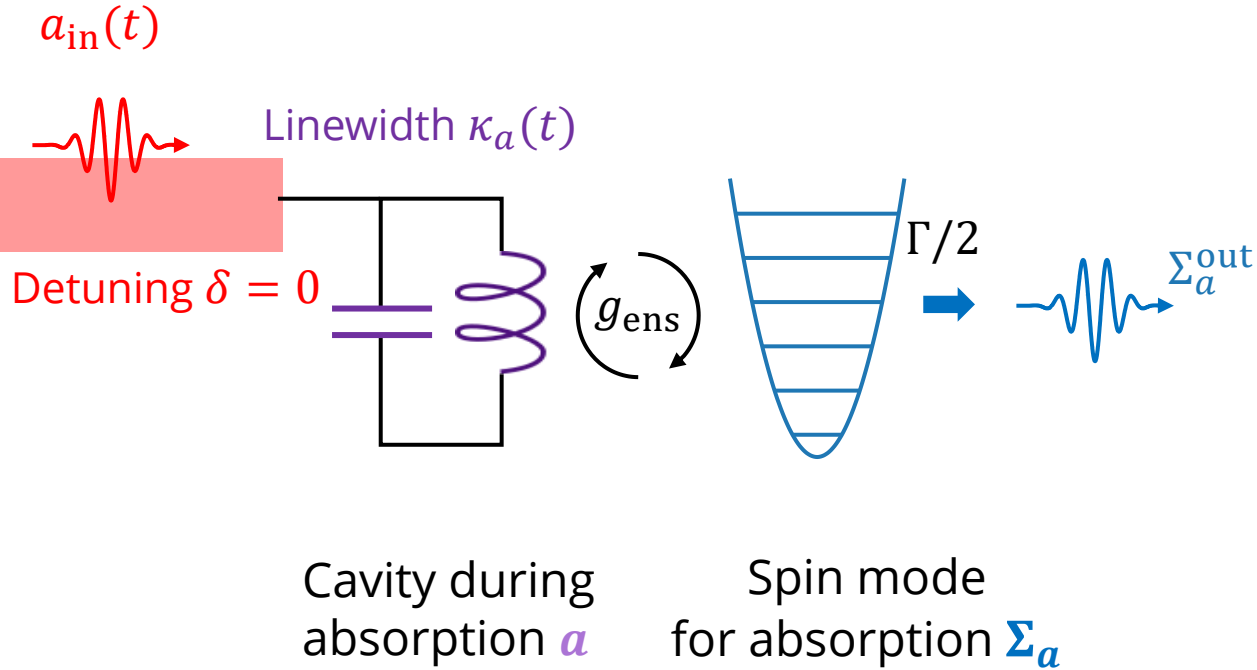
Optimal absorption ?

Problem : Maximize $\frac{\int_t |\Sigma_a^{\text{out}}|^2}{\int_t |a_{\text{in}}|^2}$



$$\begin{aligned}\dot{a} &= -\frac{[\kappa_0 + \kappa(t)]}{2} a - g_{\text{ens}} \Sigma_a + \sqrt{\kappa(t)} a_{\text{in}} \\ \dot{\Sigma}_a &= -\Gamma/2 \Sigma_a + g_{\text{ens}} a\end{aligned}$$

Optimal absorption ?



Problem : Maximize
$$\frac{\int_t |\Sigma_a^{out}|^2}{\int_t |a_{in}|^2}$$

- Opt. solution given by $\kappa(t) = \left| \frac{f_2}{f_1} \right|$
- Theoretical bound on absorption efficiency

$$\eta_a = \frac{1}{\min_{\kappa > 0} \int_t |a_{in}|^2} \leq \frac{1}{\int_t 4f_1 f_2} \leq \frac{\kappa_s}{\kappa_0 + \kappa_s}$$

$$\begin{aligned} \dot{a} &= -\frac{[\kappa_0 + \kappa(t)]}{2} a - g_{ens} \Sigma_a + \sqrt{\kappa(t)} a_{in} \\ \dot{\Sigma}_a &= -\Gamma/2 \Sigma_a + g_{ens} a \end{aligned}$$



$$a_{in} = \sqrt{\kappa} f_1(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a) + \frac{1}{\sqrt{\kappa}} f_2(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a)$$

$$f_1 = \frac{1}{4 g_{ens}} (\Gamma \Sigma_a + 2 \dot{\Sigma}_a)$$

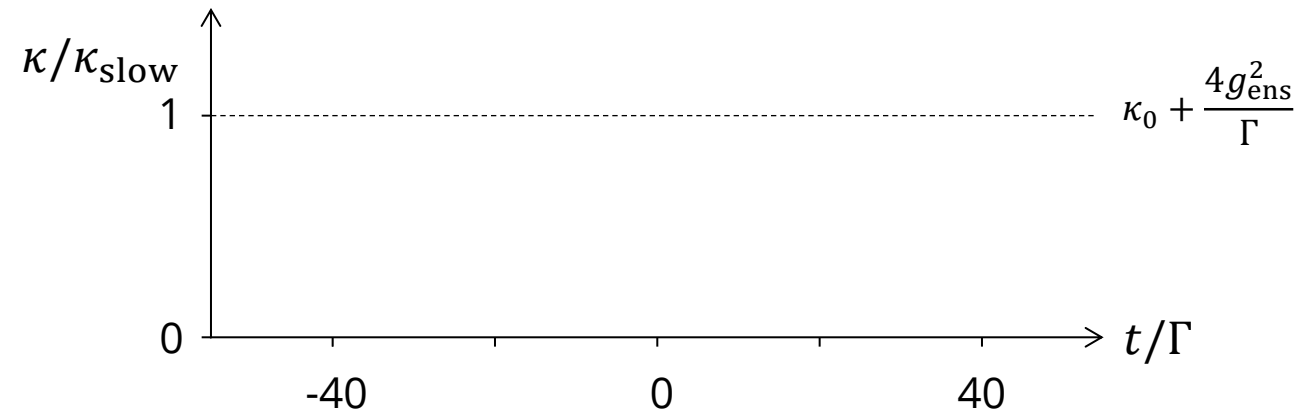
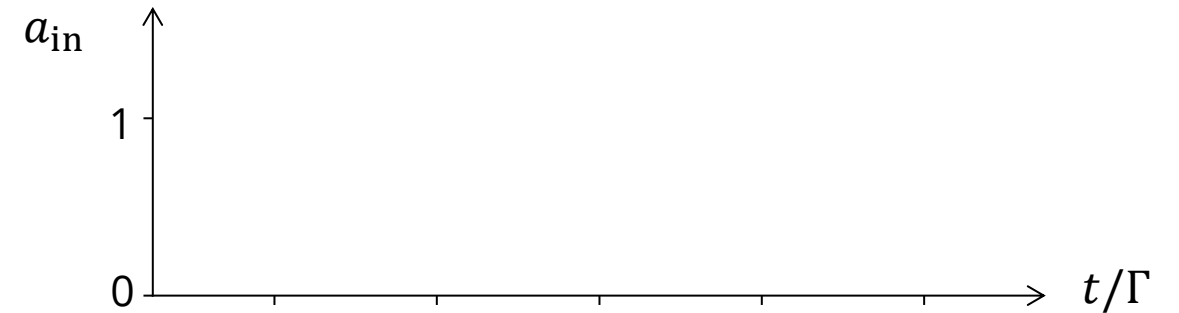
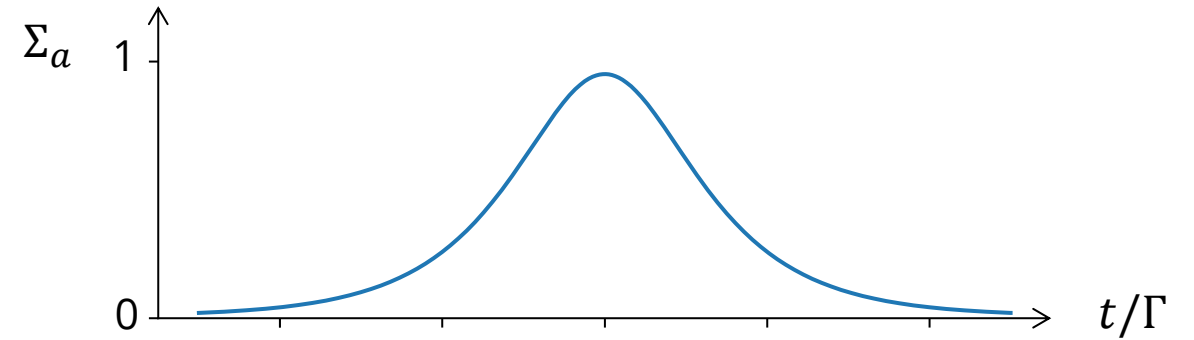
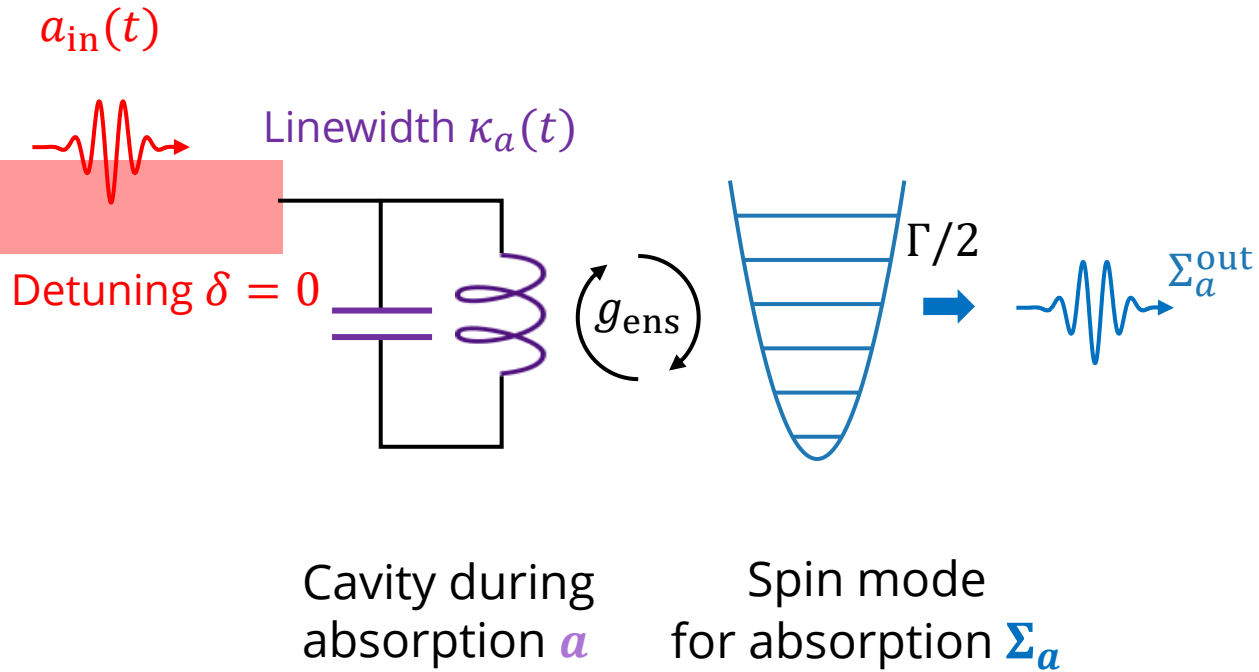
$$f_2 = \frac{1}{g_{ens}} \left(\left(\frac{g_{ens}^2}{\Gamma} + \kappa_0 \right) \Sigma_a + \left(\frac{\Gamma}{2} + \frac{\kappa_0}{2} \right) \Gamma \dot{\Sigma}_a + \Gamma^2 \ddot{\Sigma}_a \right)$$

Numerical simulations

Let's consider $\Sigma_a = \frac{1}{\cosh(\alpha\Gamma t)}$

$$\kappa_0 = 0.03 \Gamma$$

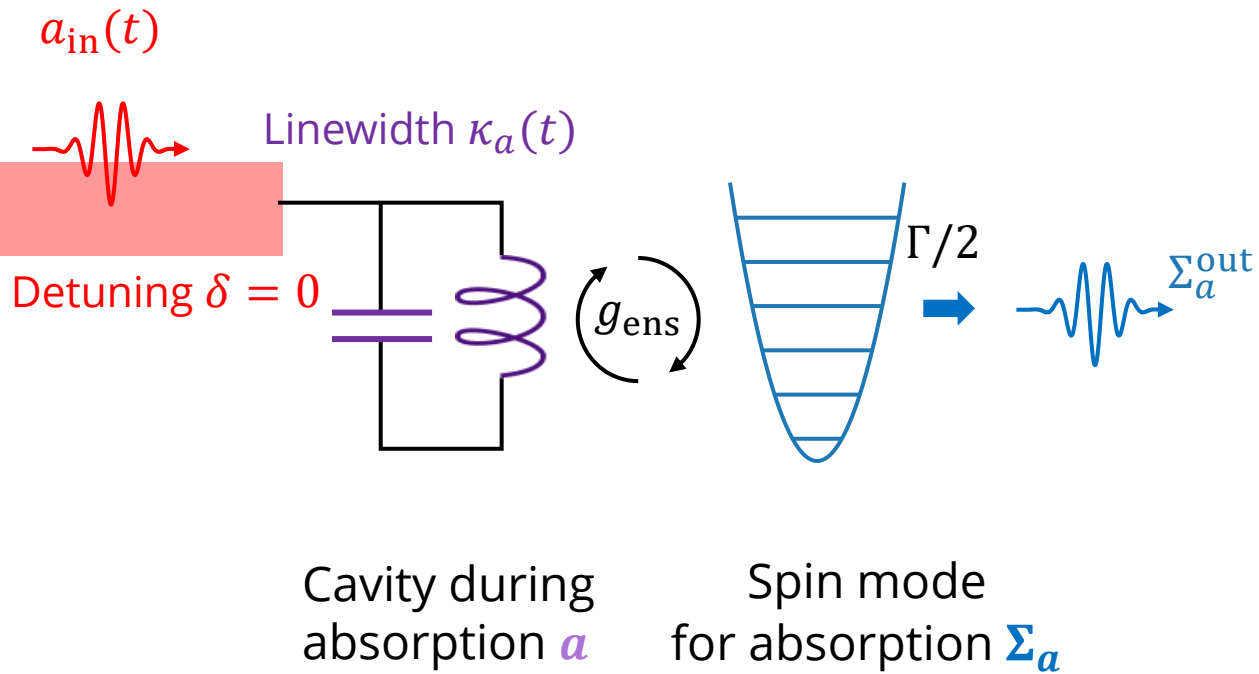
$$g_{\text{ens}} = \Gamma/2$$



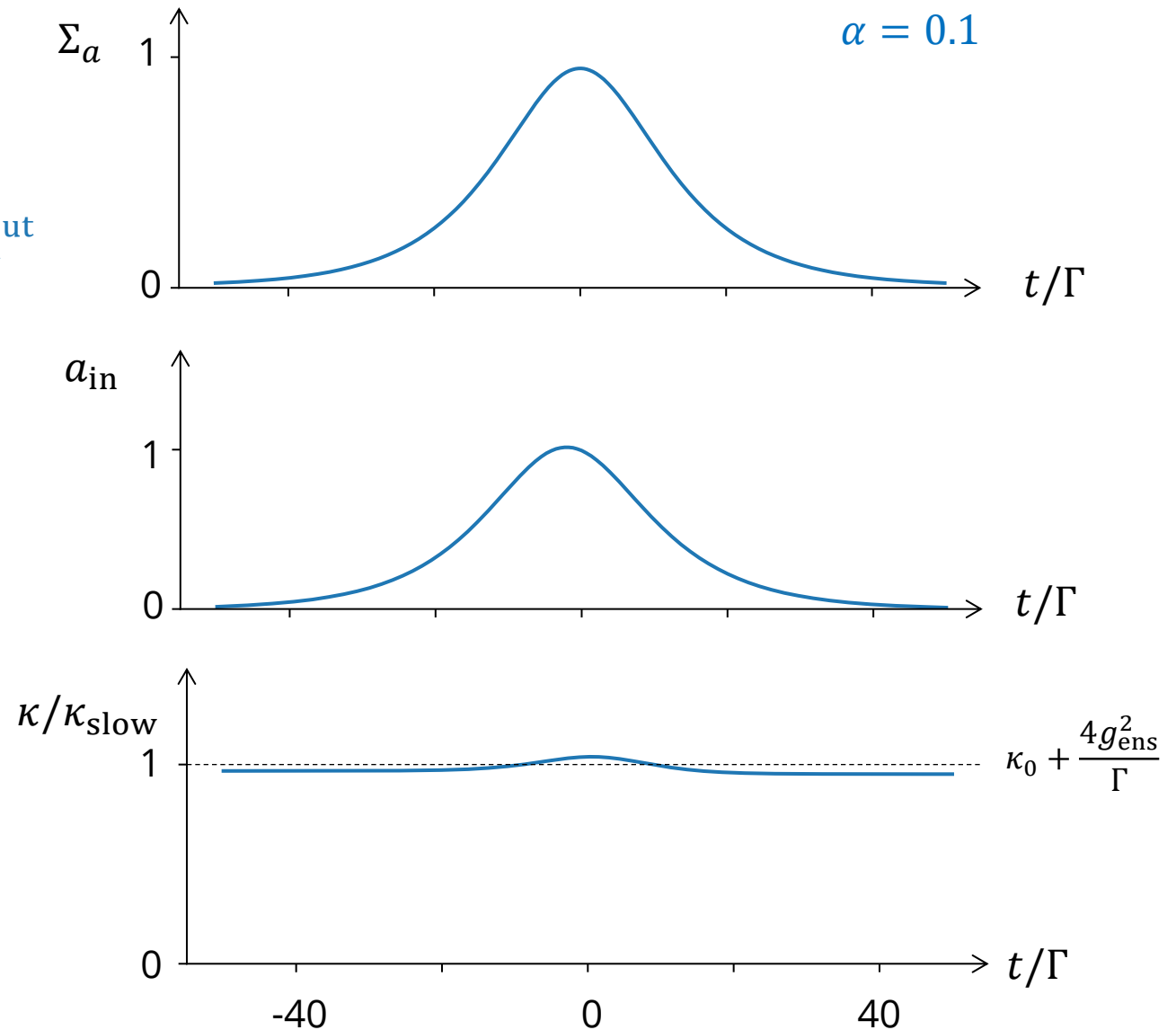
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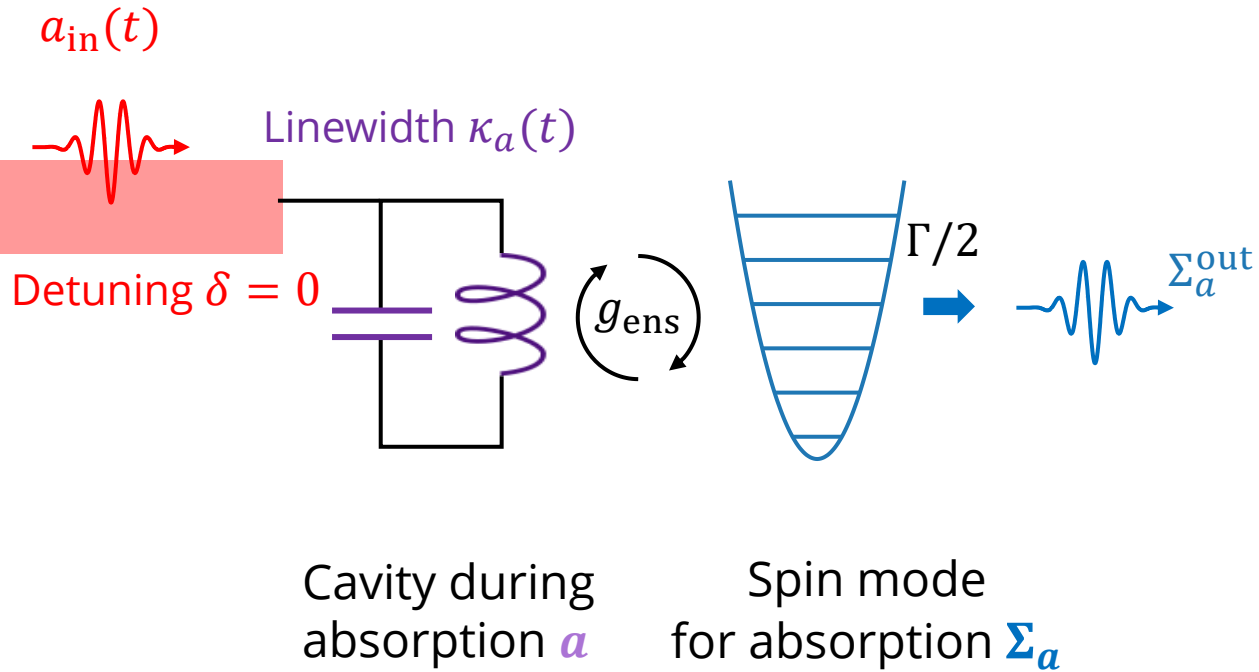
$$\begin{cases} a = f(\Sigma_a, \dot{\Sigma}_a) \text{ and so} \\ a_{\text{in}} = \sqrt{\kappa} f_1(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a) + \frac{1}{\sqrt{\kappa}} f_2(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a) \\ \kappa_a(t) = \left| \frac{f_2(t)}{f_1(t)} \right| \end{cases}$$



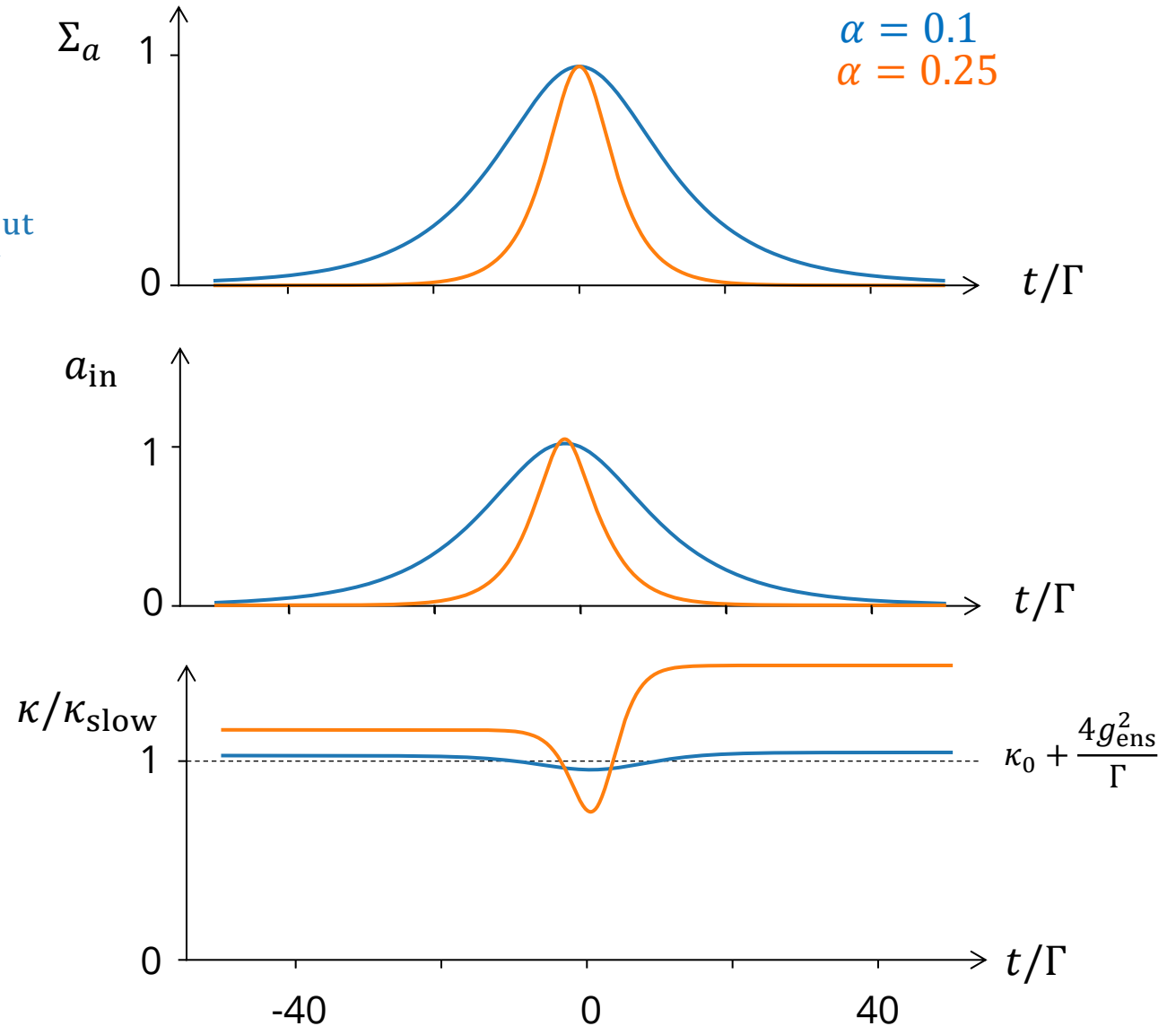
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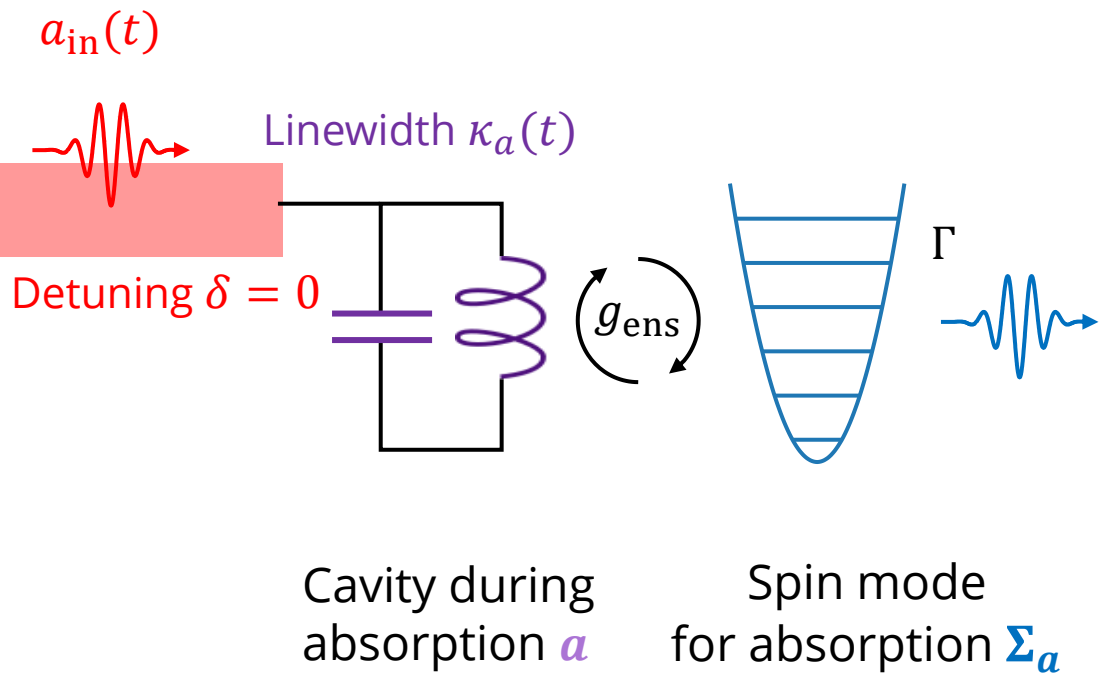
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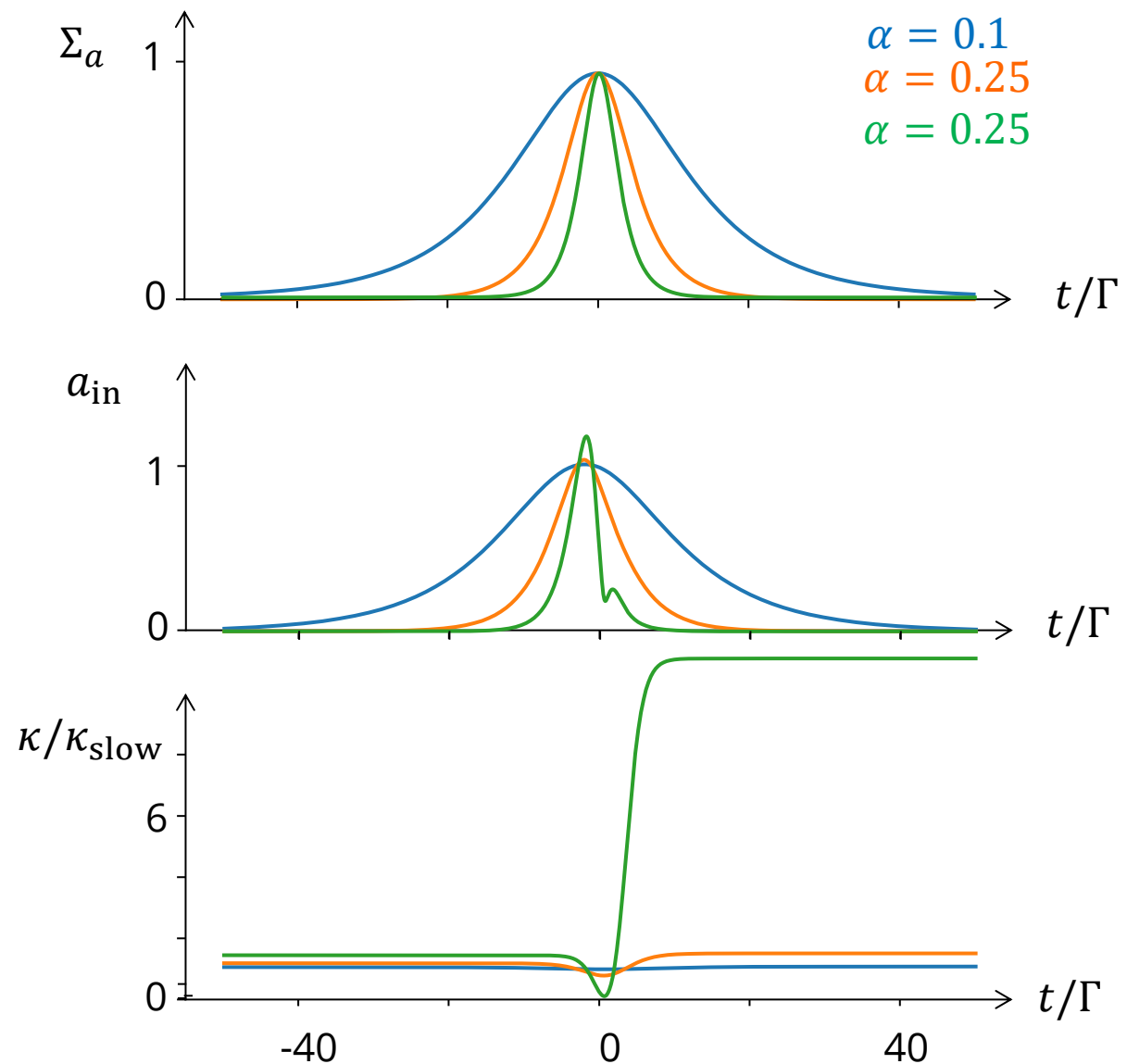
Numerical simulations



$$\begin{cases}
 a = f(\Sigma_a, \dot{\Sigma}_a) \text{ and so} \\
 a_{\text{in}} = \sqrt{\kappa} f_1(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a) + \frac{1}{\sqrt{\kappa}} f_2(\Sigma_a, \dot{\Sigma}_a, \ddot{\Sigma}_a) \\
 \kappa_a(t) = \left| \frac{f_2(t)}{f_1(t)} \right|
 \end{cases}$$

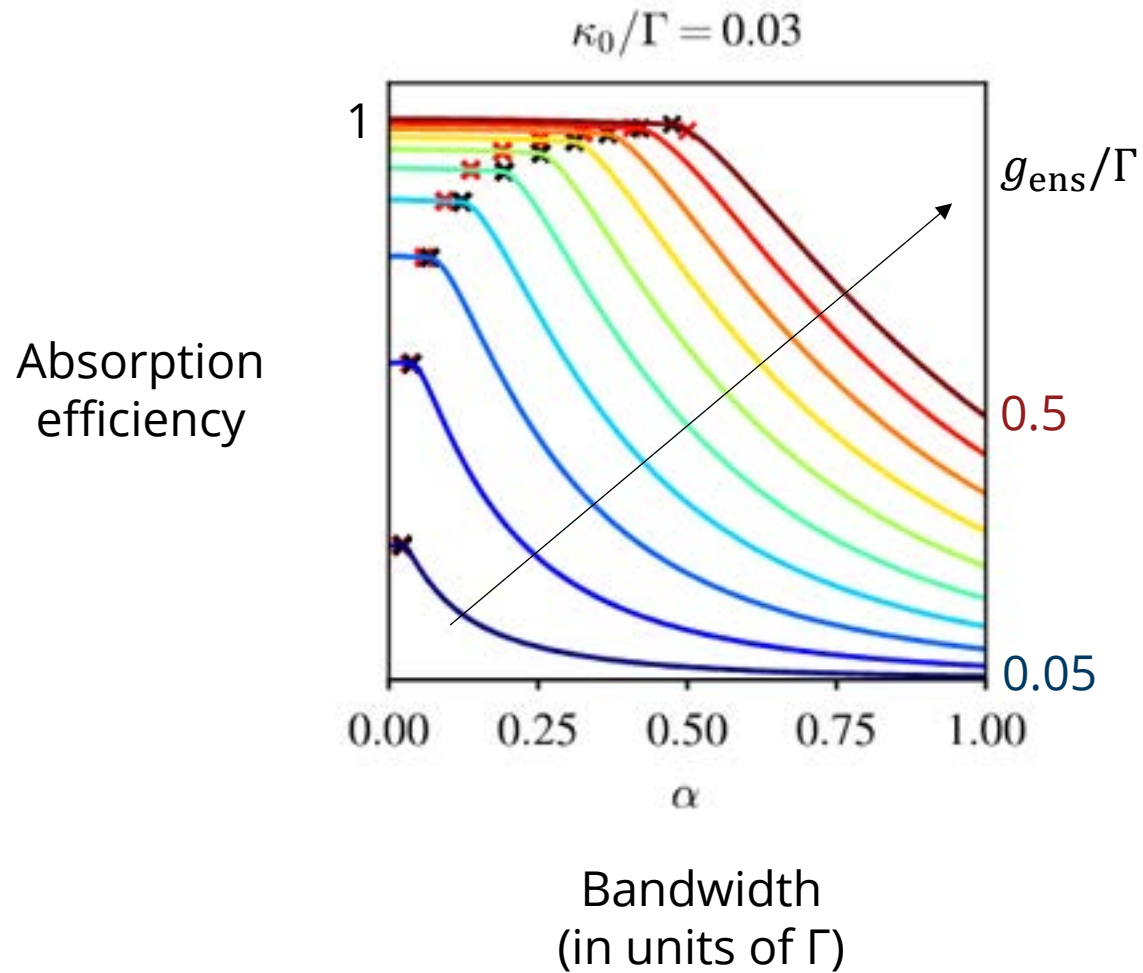
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$$\begin{aligned}
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 g_{\text{ens}} &= \Gamma/2
 \end{aligned}$$



Numerical simulations

$$\kappa_0 = 0.03 \Gamma$$
$$g_{\text{ens}} = \Gamma/2$$



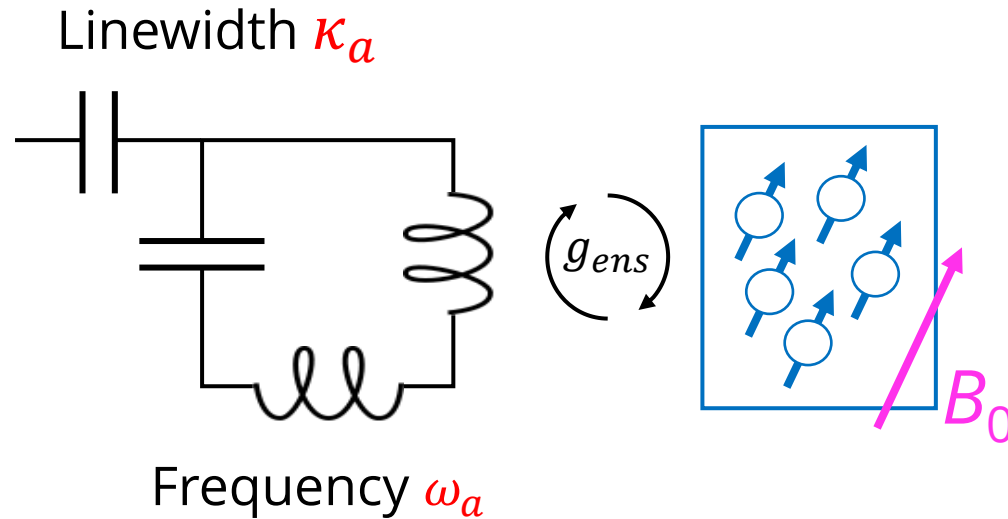
Higher coupling means higher efficiency

Max. absorption bandwidth given by $\Gamma/2$

L. Greggio, to appear in *PRA*, 2026

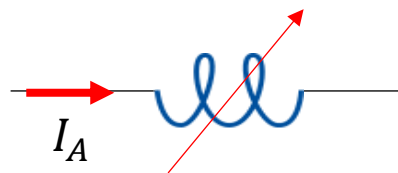
other approach : J. Bernad, *J. Phys. B: At. Mol. Opt. Phys.* 2025

Quantum memory requirements

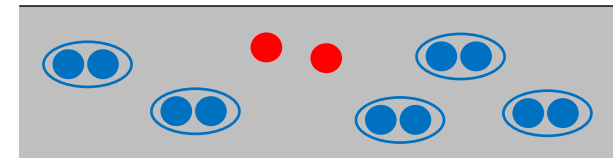


- ☐ Long spin coherence
 - Aim for clock transitions
- ☐ Reach unit cooperativity
- ☐ **Tunable** resonator frequency
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- ☐ **Tunable** linewidth
 - ☐ For cooperativity tuning
 - ☐ For perfect absorption

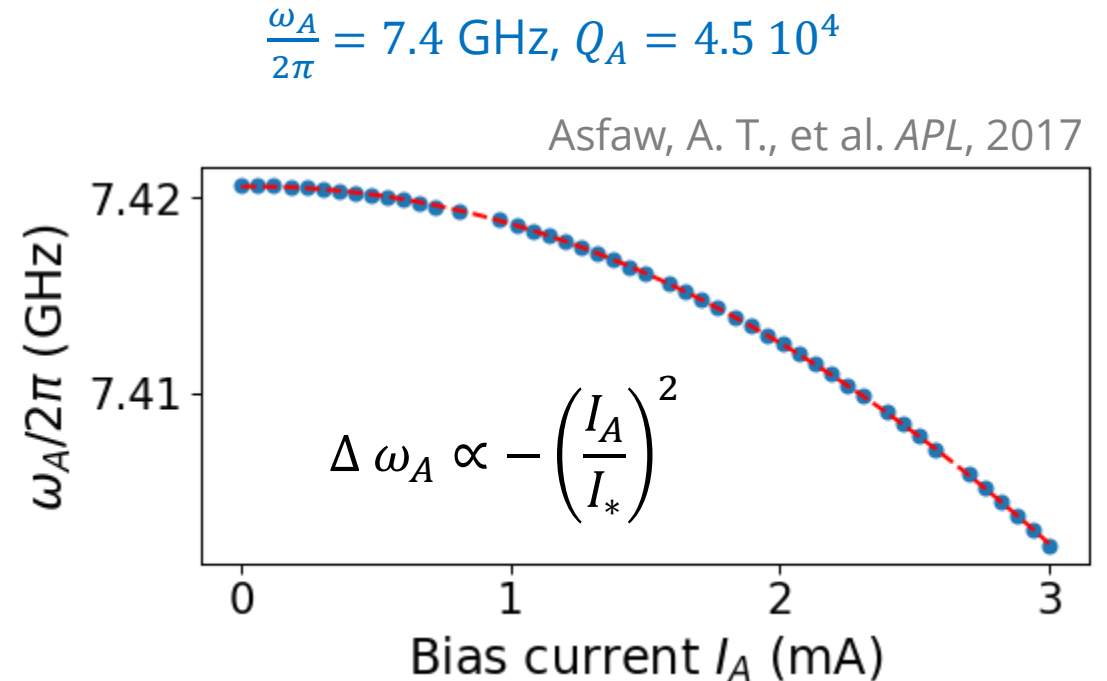
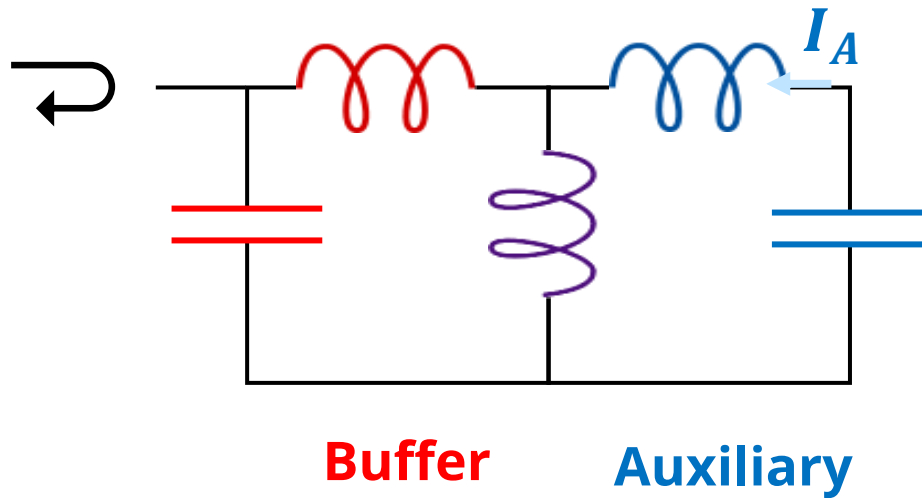
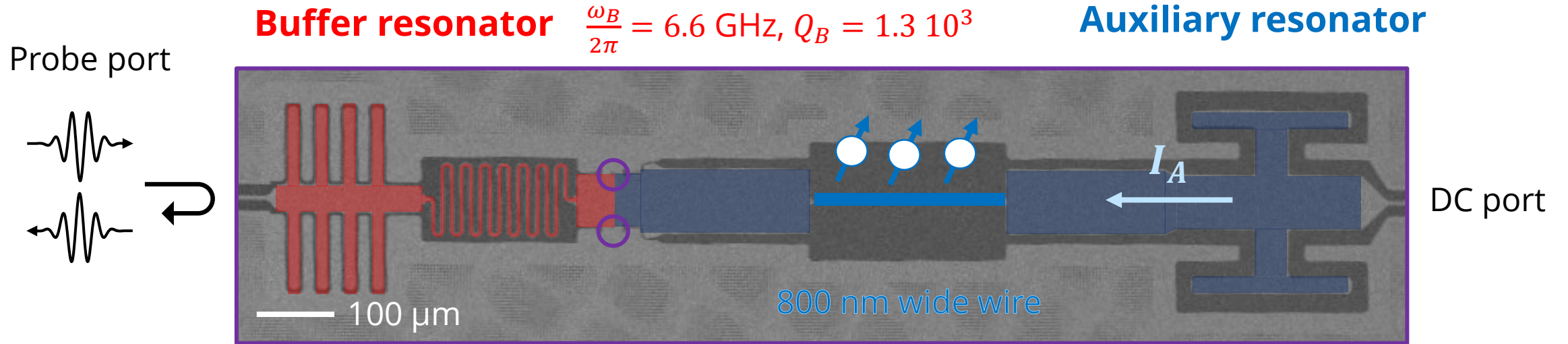
Tuning a superconducting circuit in magnetic field: kinetic inductance of the film



$$L(I_A) = L_G + L_{kin} + L_{kin} \left(\frac{I_A}{I_*} \right)^2$$

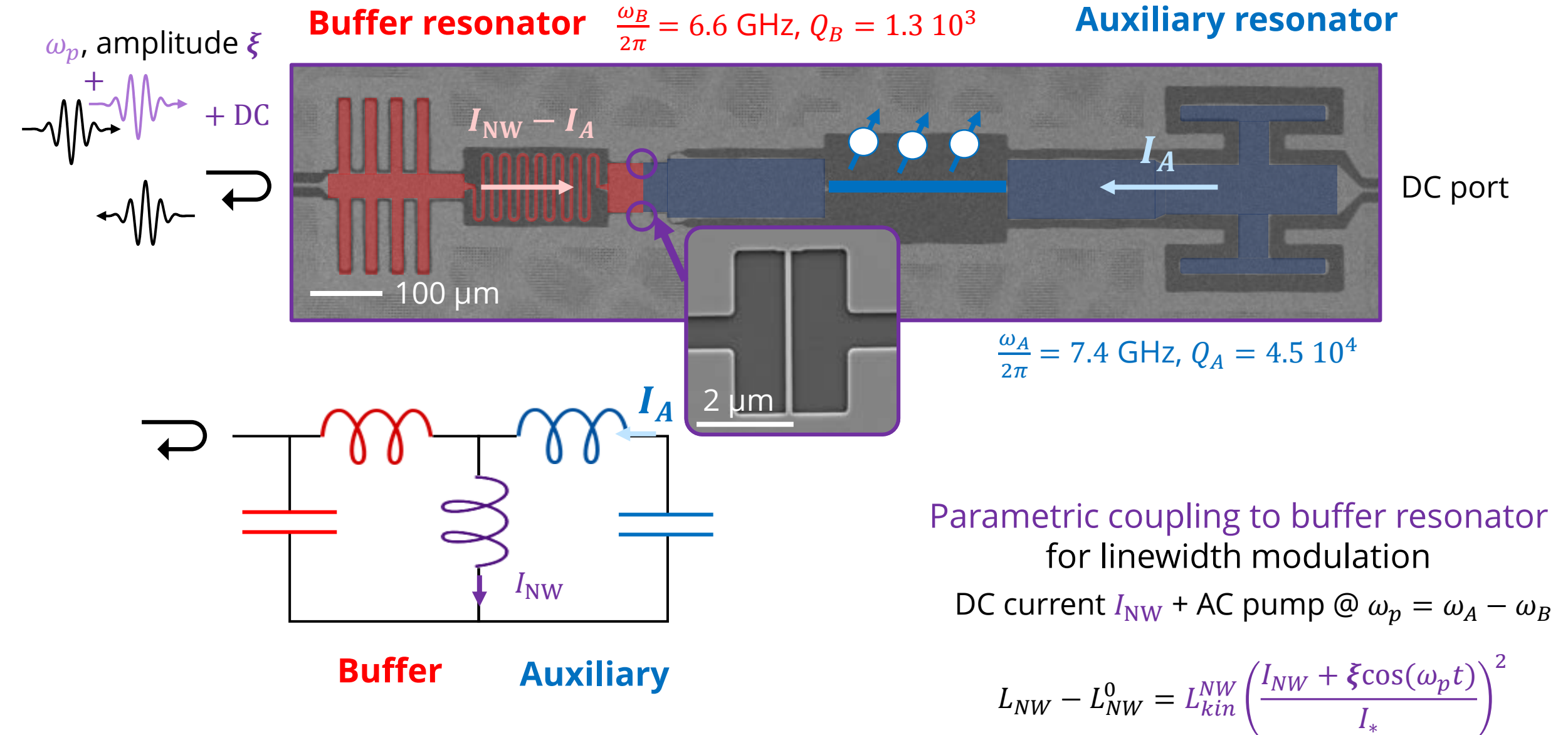


The device, version 1



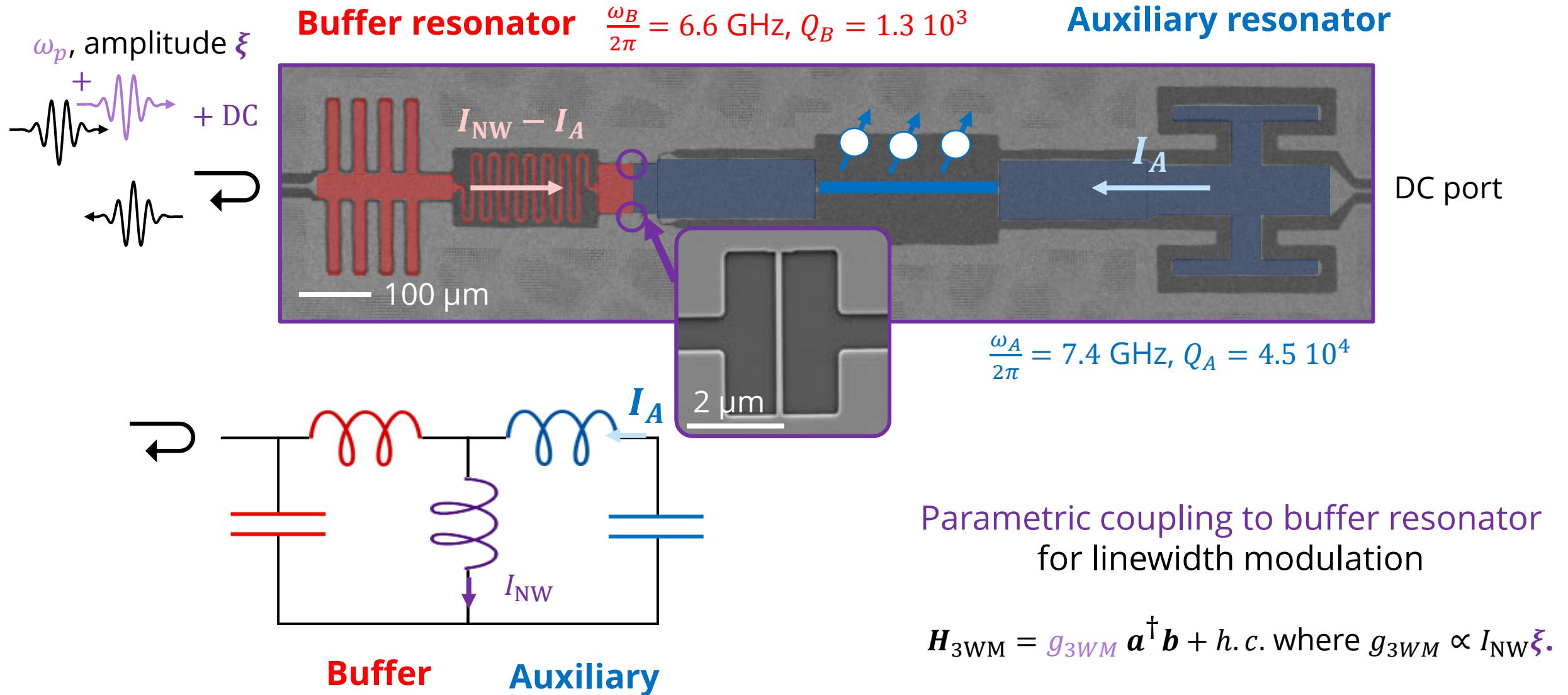
50-nm NbTiN ($L_{\text{kin}} = 2 \text{ pH}/\square$) on silicon

The device : frequency tuning



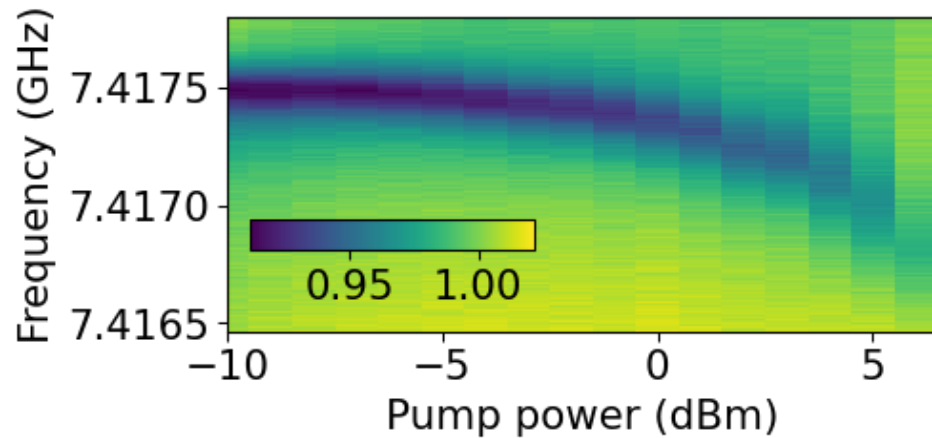
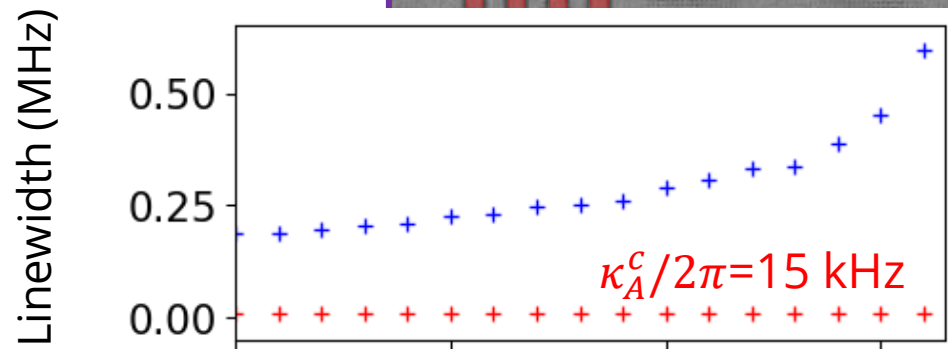
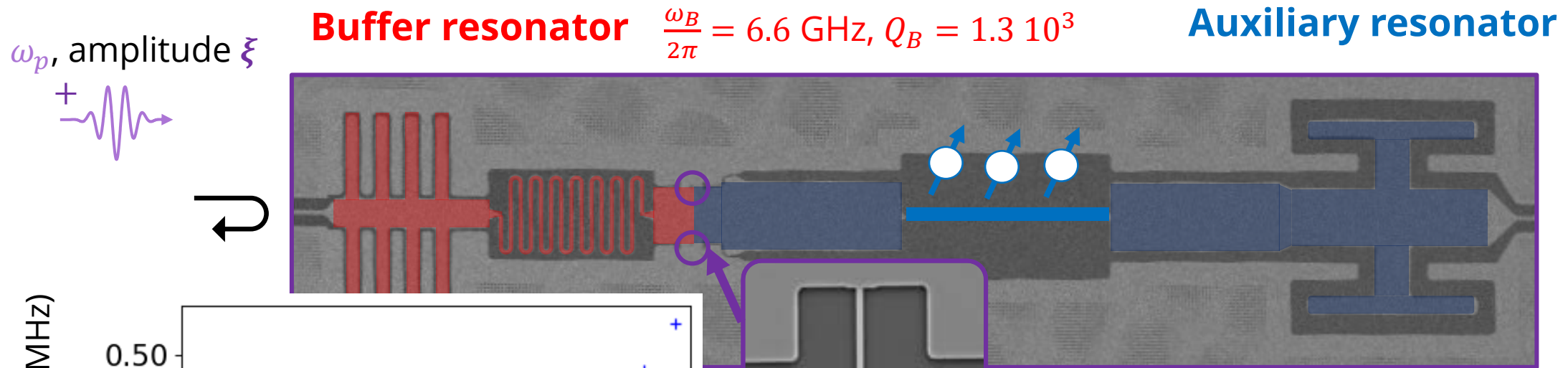
50-nm NbTiN ($L_{kin} = 2 \text{ pH}/\square$) on silicon

The device : frequency tuning



50-nm NbTiN ($L_{\text{kin}} = 2 \text{ pH}/\square$) on silicon

The device: three-wave mixing



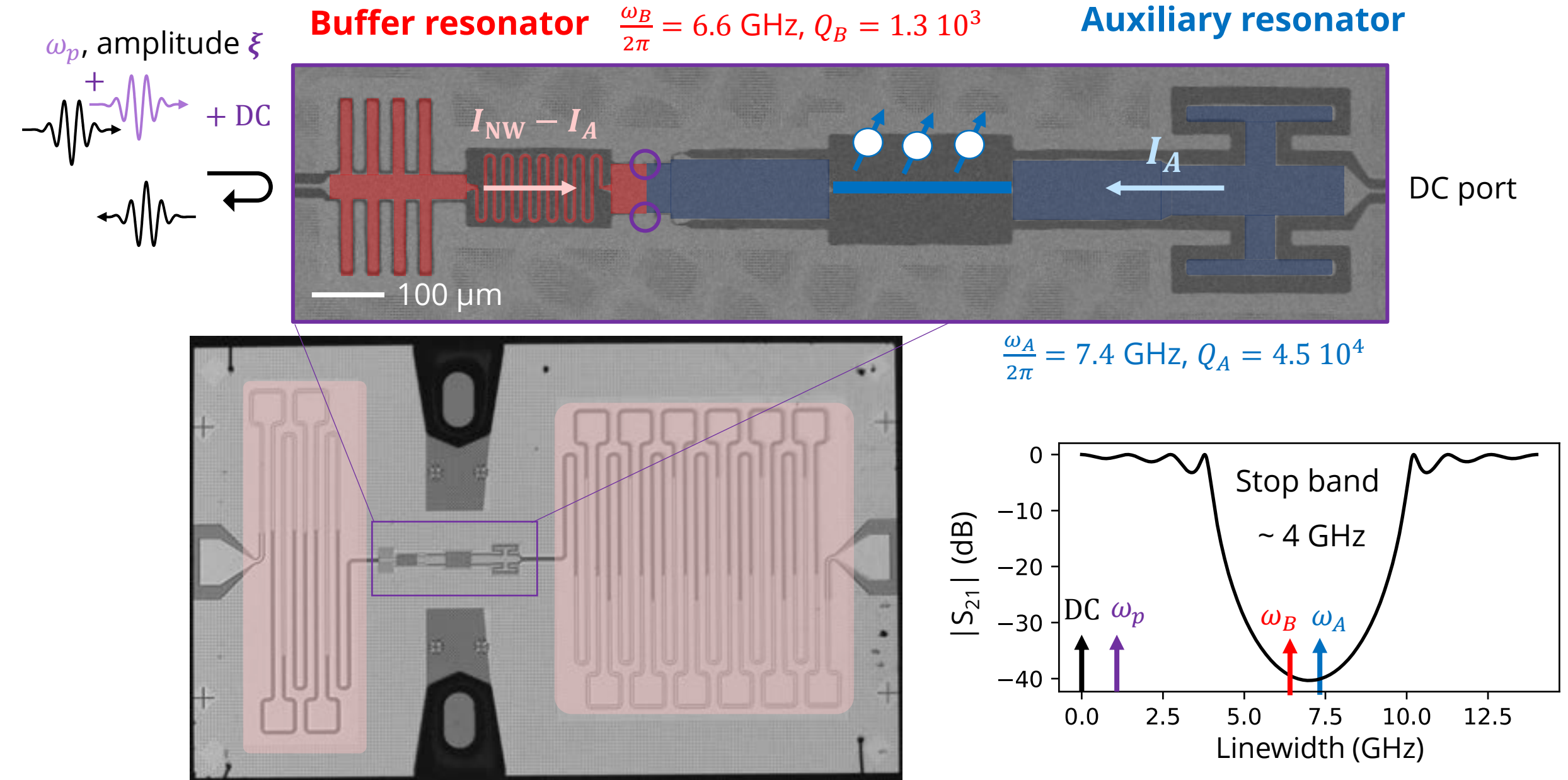
Parametric coupling to buffer resonator
for linewidth modulation

$$\mathbf{H}_{3WM} = g_{3WM} \mathbf{a}^\dagger \mathbf{b} + h.c., \text{ if } \omega_p + \omega_B = \omega_A$$

$$\text{Effective linewidth } \kappa_A^{\text{eff}} = \kappa_A + \frac{4g_{3WM}^2}{\kappa_B}$$

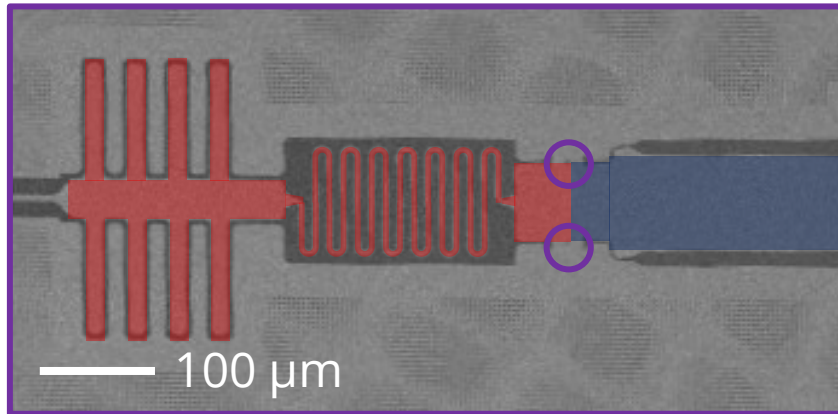
$$\text{where } g_{3WM} \propto I_{\text{NW}} \xi.$$

The device : tuning via Bragg filters

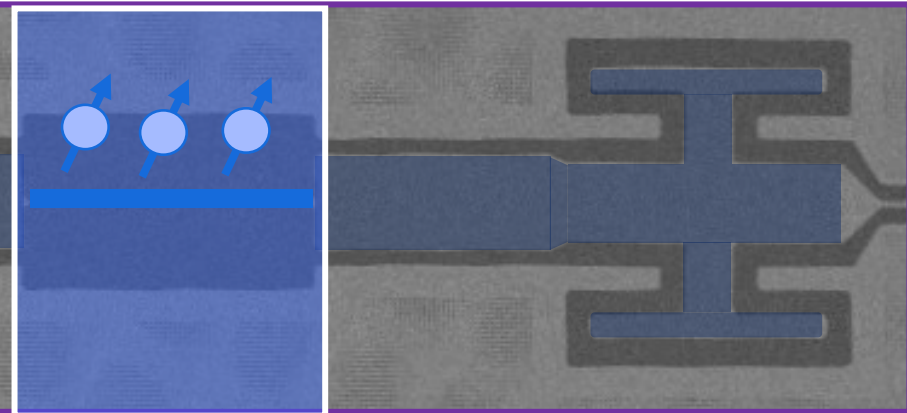


The device : spins

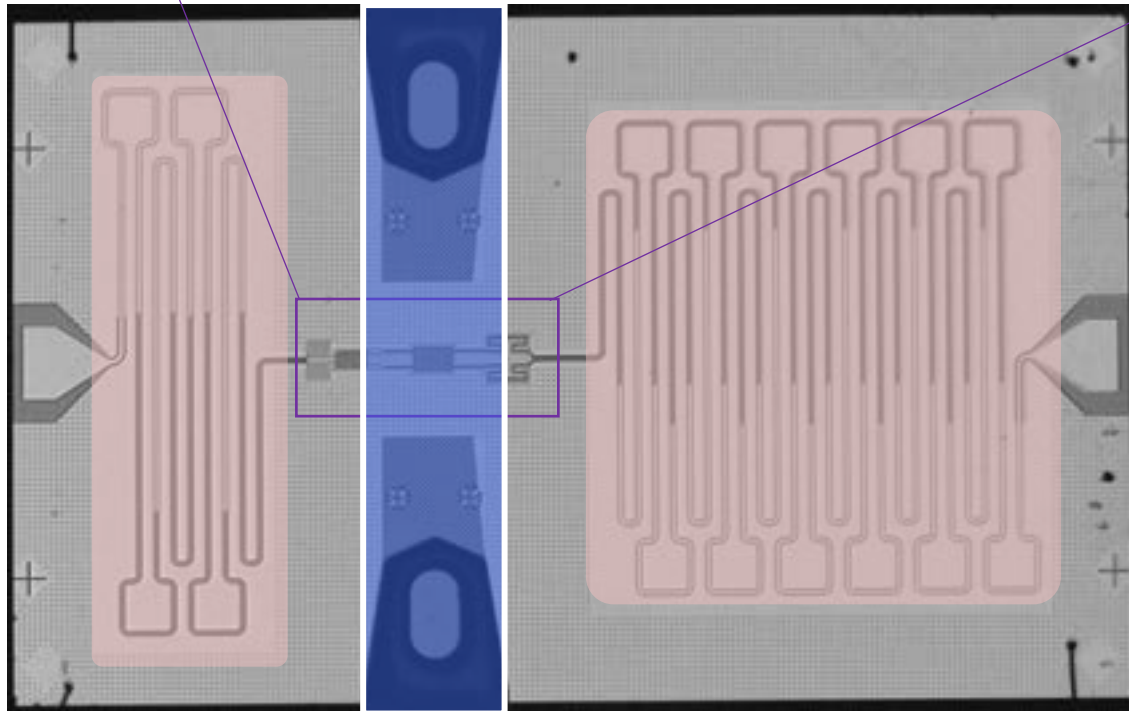
Buffer resonator



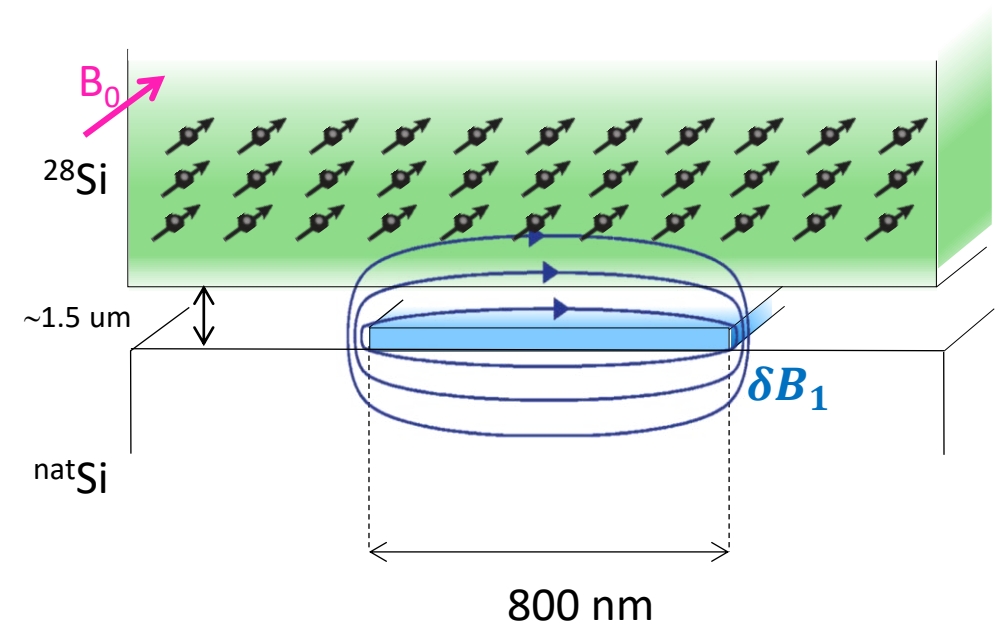
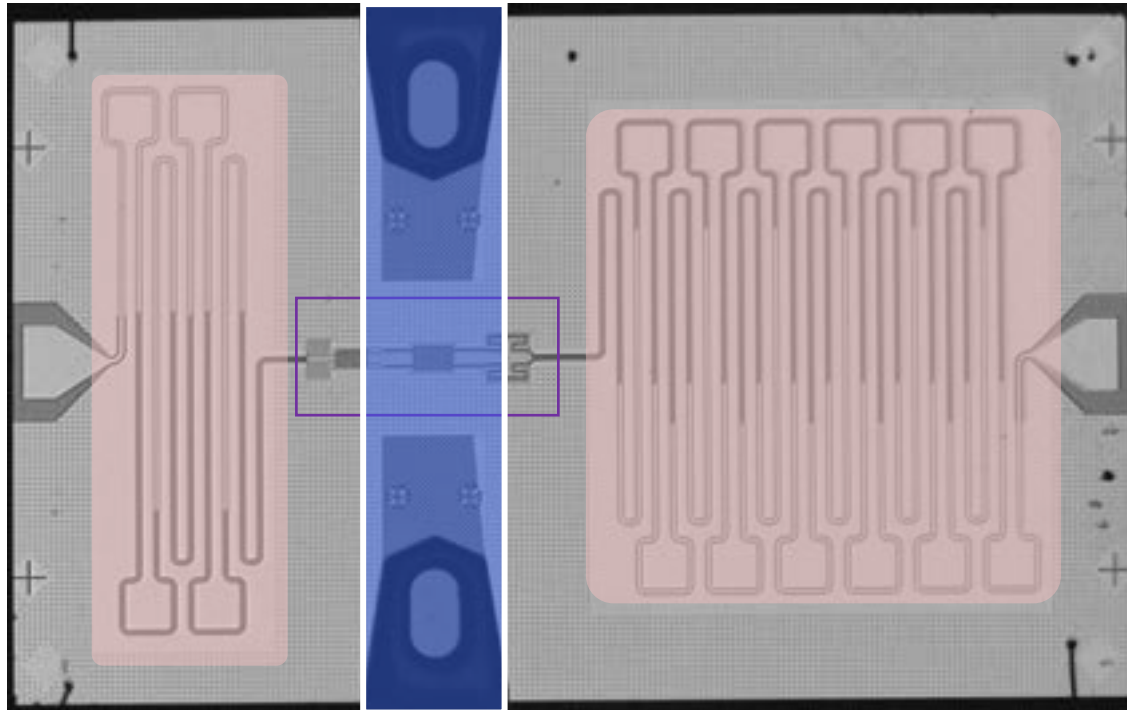
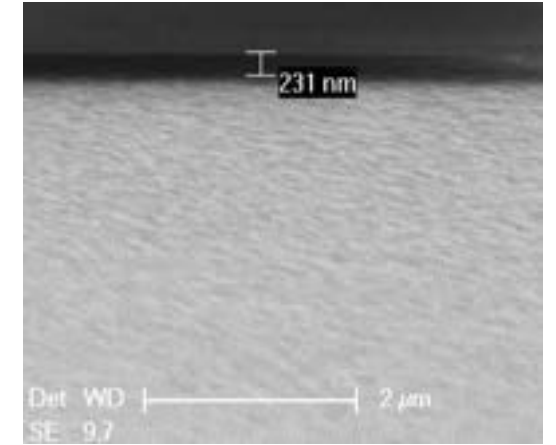
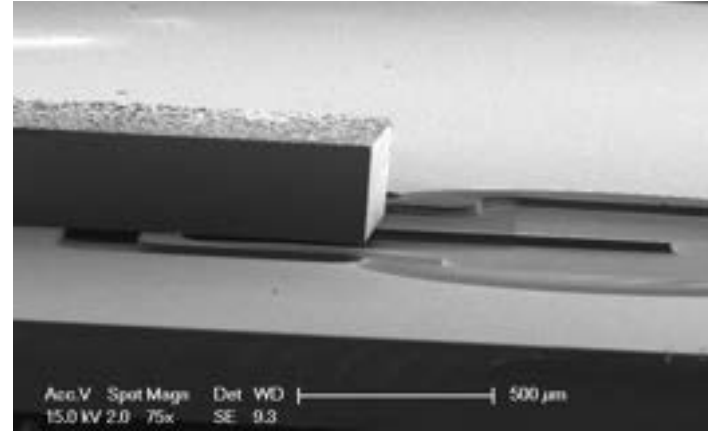
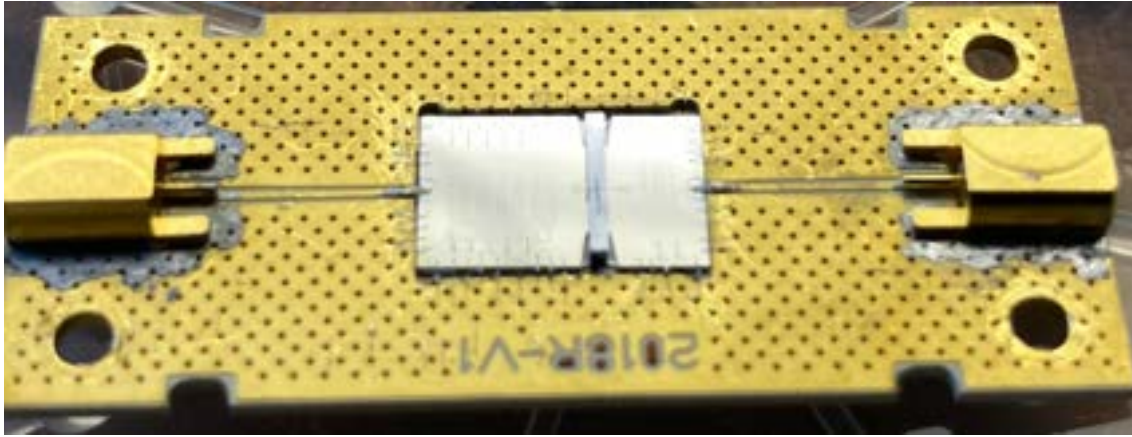
Auxiliary resonator



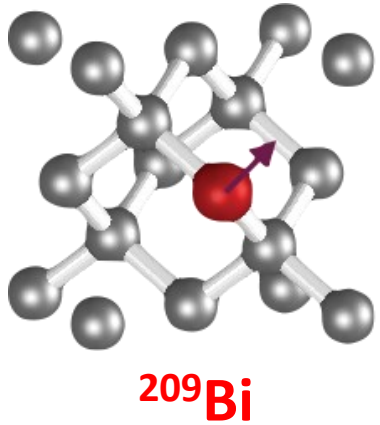
$$\frac{\omega_A}{2\pi} = 7.4 \text{ GHz}, Q_A = 4.5 \cdot 10^4$$



The device : spins

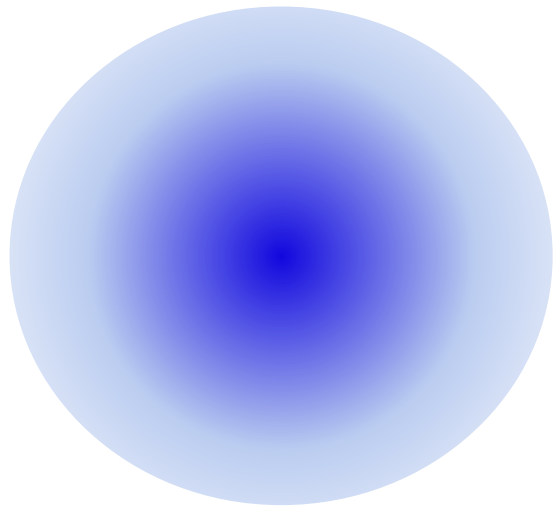


Bismuth donors in silicon



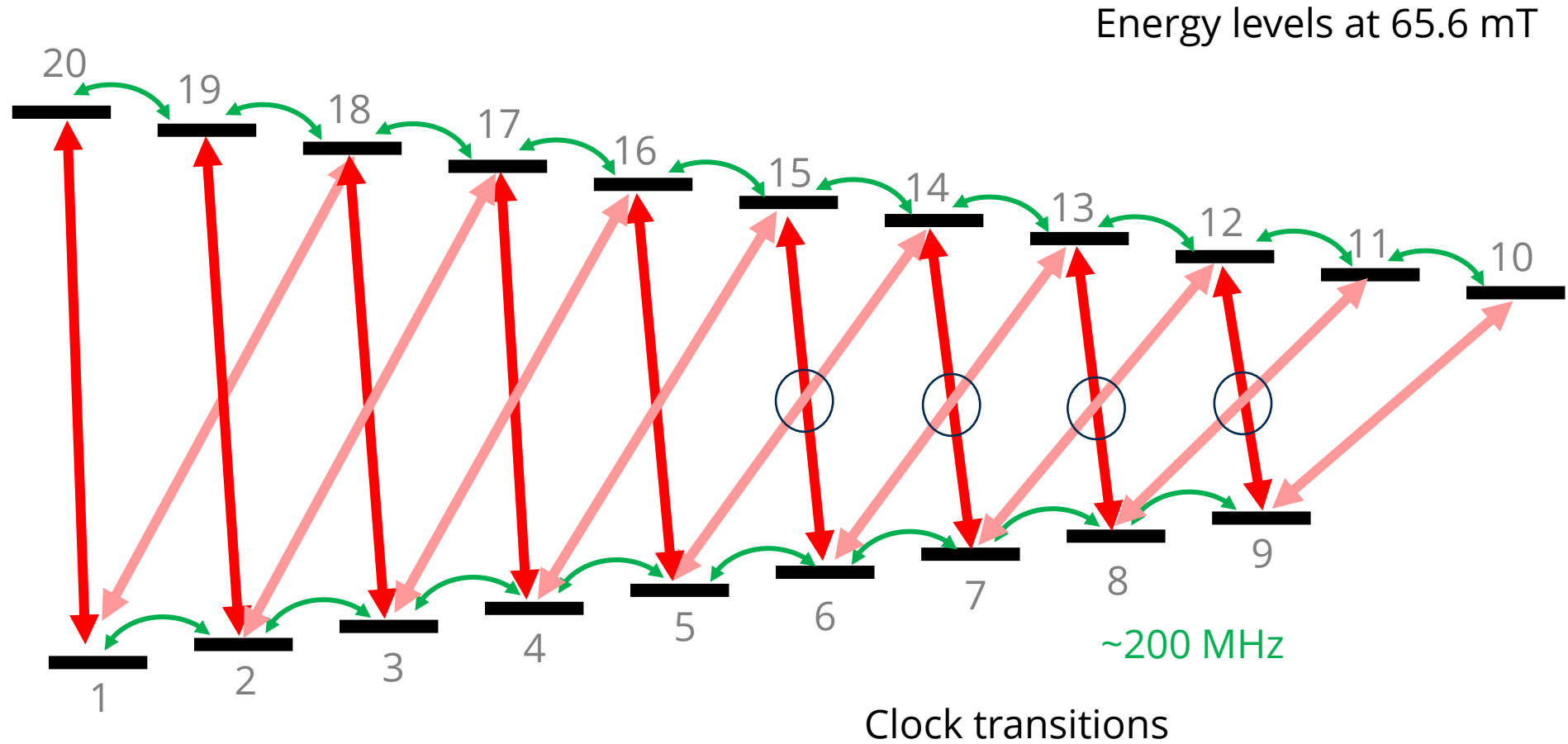
Nuclear spin
 $I = 9/2$

Bismuth donors in silicon



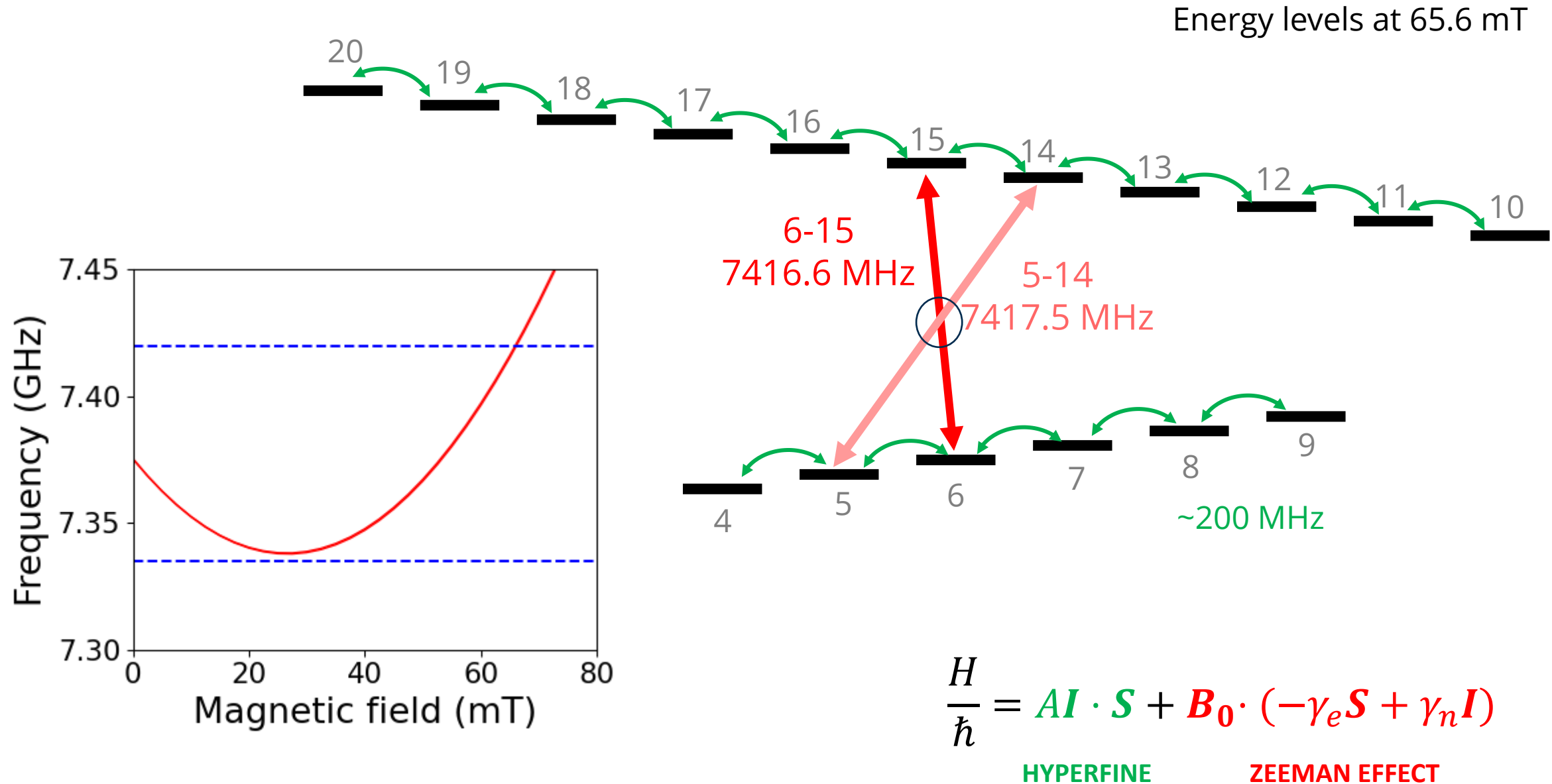
Nuclear spin
 $I = 9/2$

Electronic spin
 $S = 1/2$

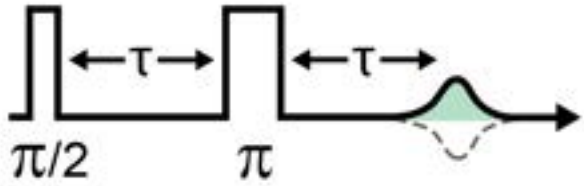


$$\frac{H}{\hbar} = \underbrace{AI \cdot \mathbf{S}}_{\text{HYPERFINE}} + \underbrace{\mathbf{B}_0 \cdot (-\gamma_e \mathbf{S} + \gamma_n \mathbf{I})}_{\text{ZEEMAN EFFECT}}$$

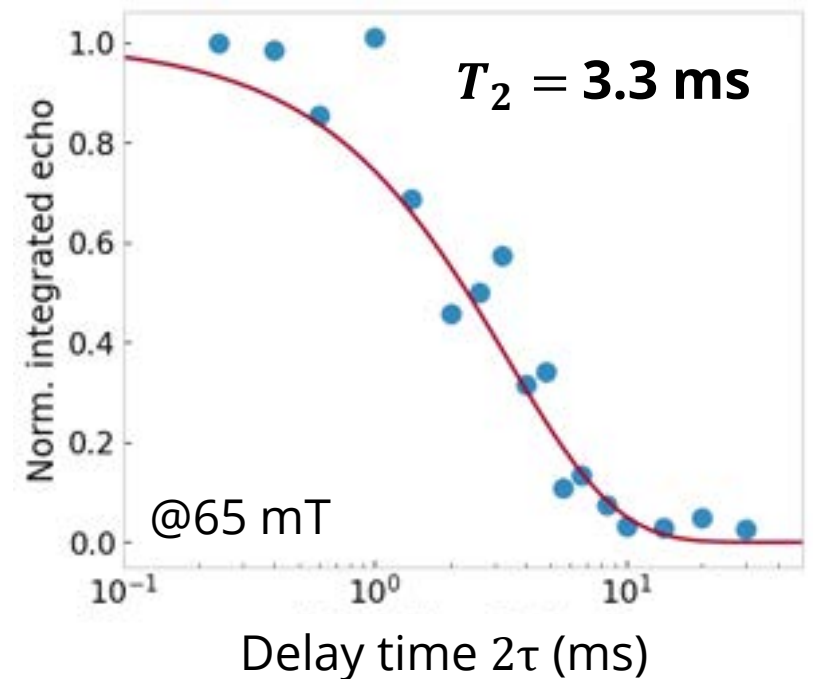
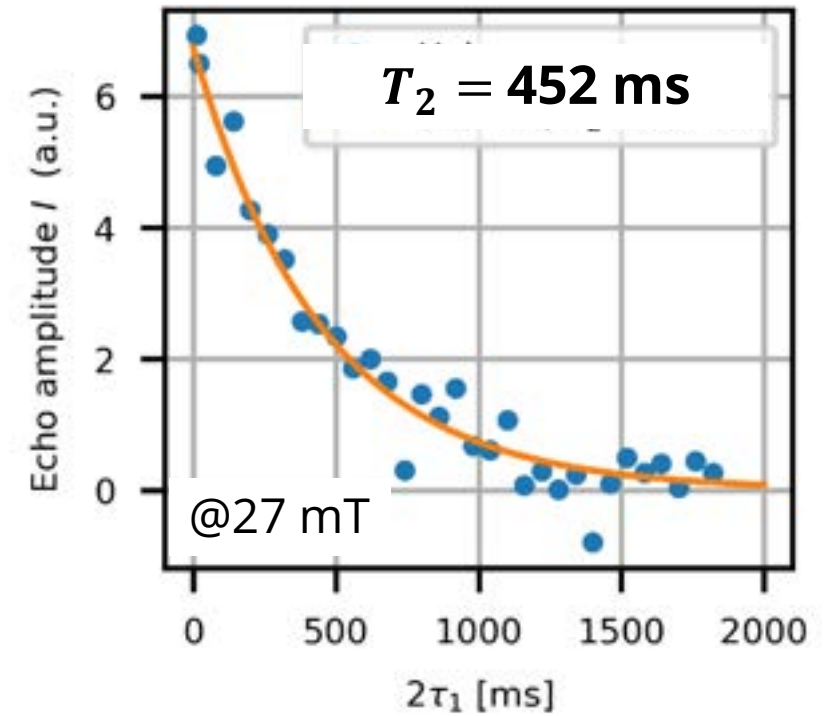
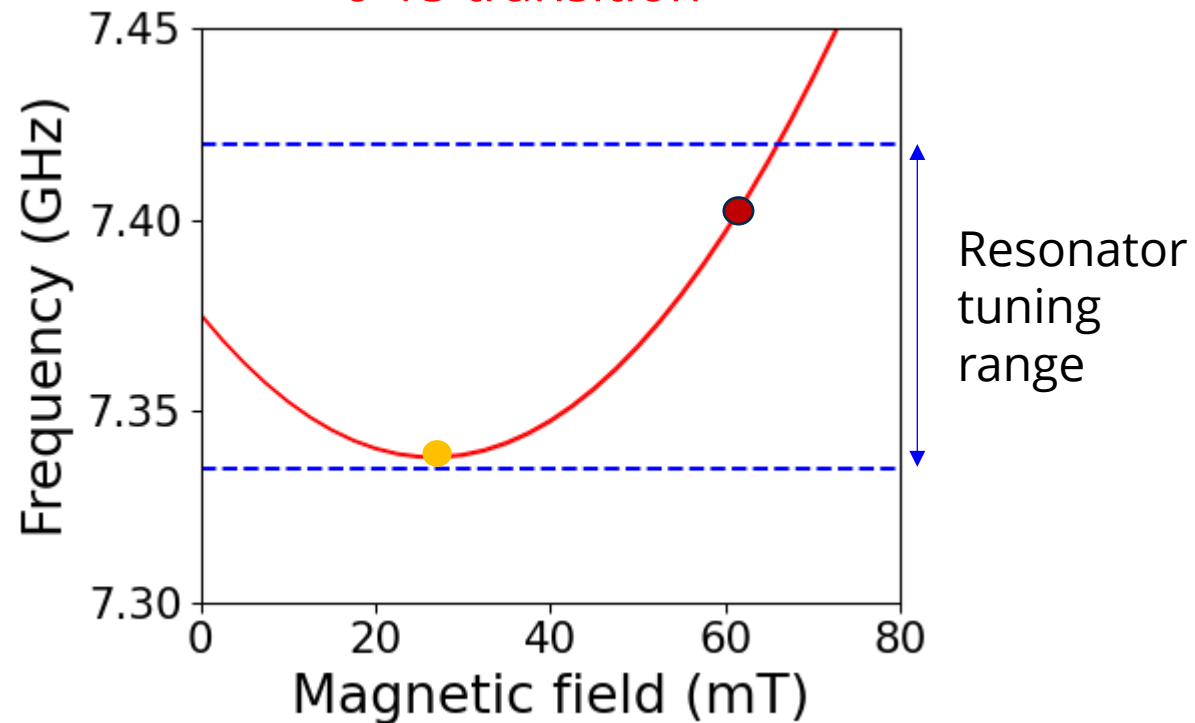
Bismuth donors in silicon



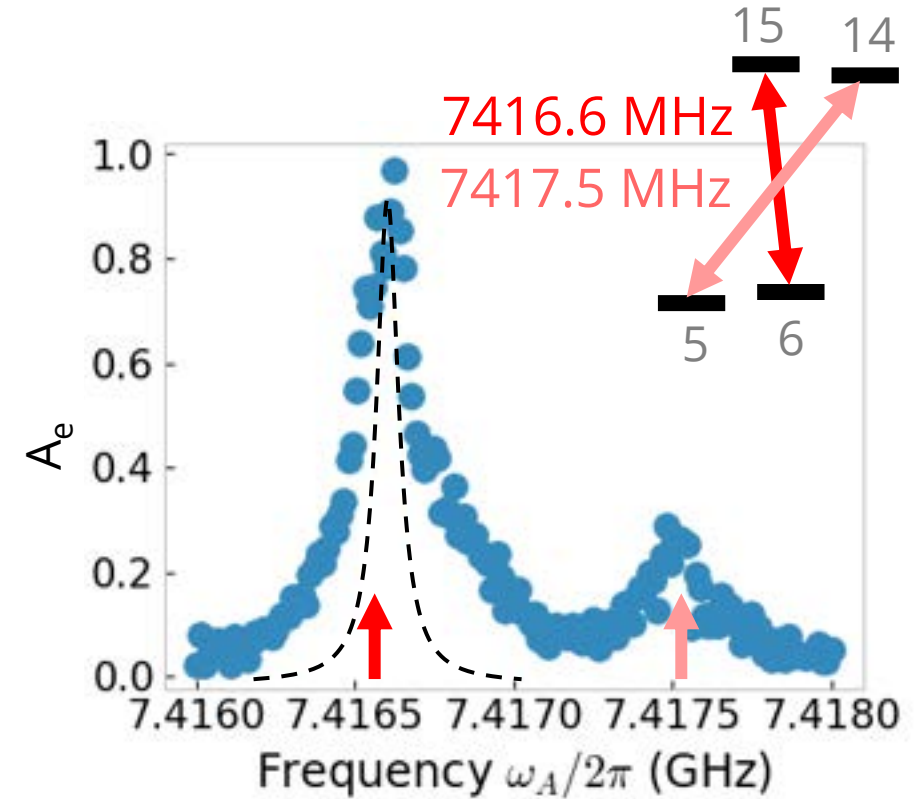
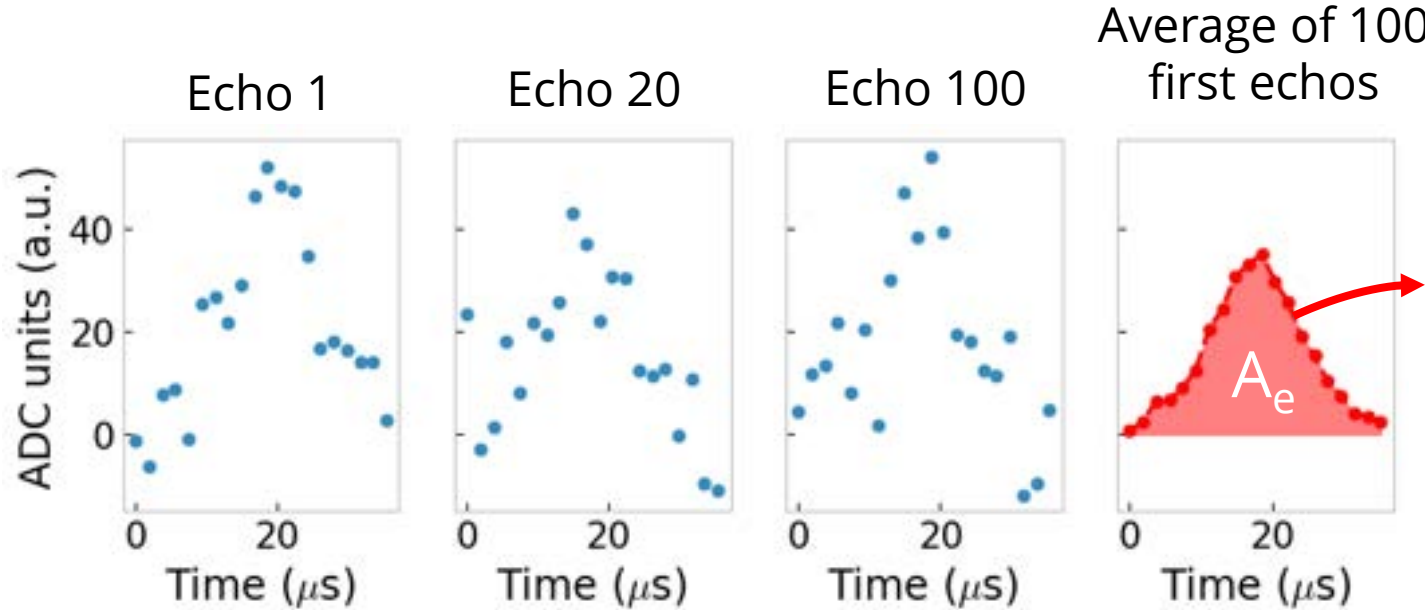
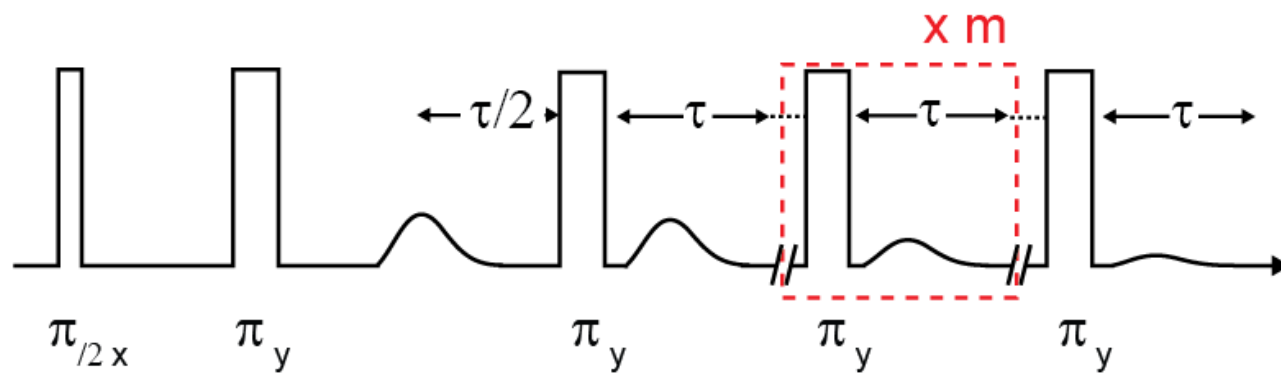
Bismuth donors in silicon



6-15 transition



Pulsed echo measurement with CPMG

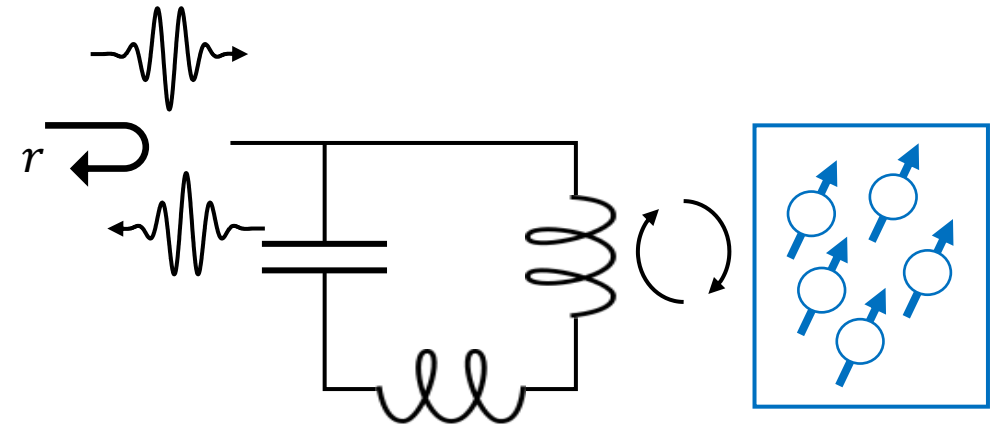
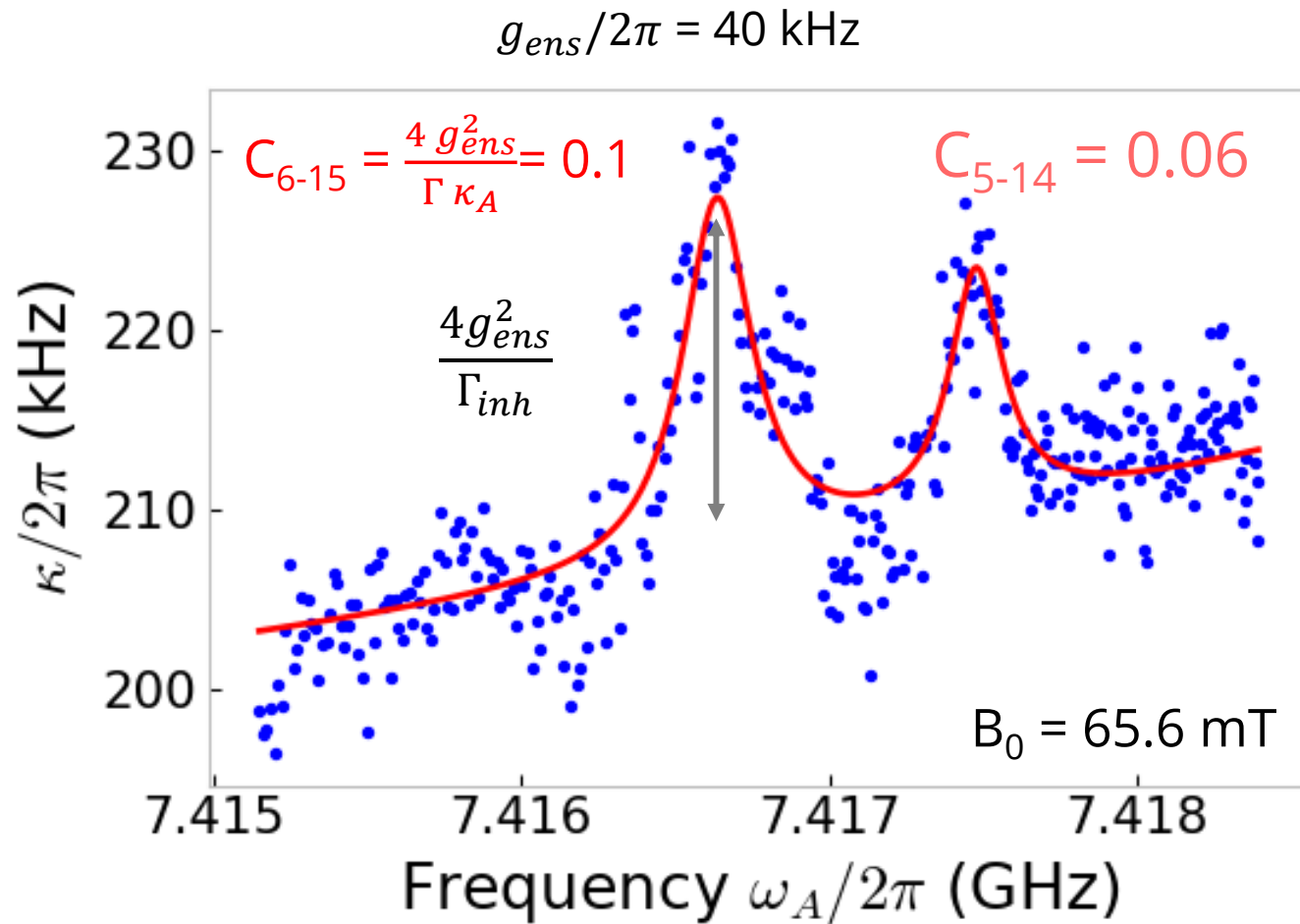


Resonator linewidth
 $\kappa_A / 2\pi = 185 \text{ kHz}$

Inhomogeneous broadening
 $\Gamma / 2\pi = 300 \text{ kHz}$

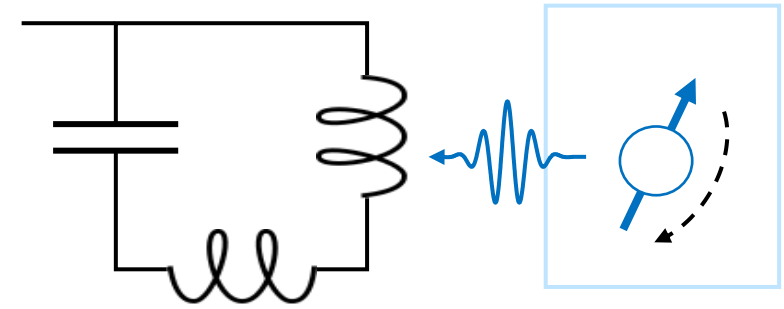
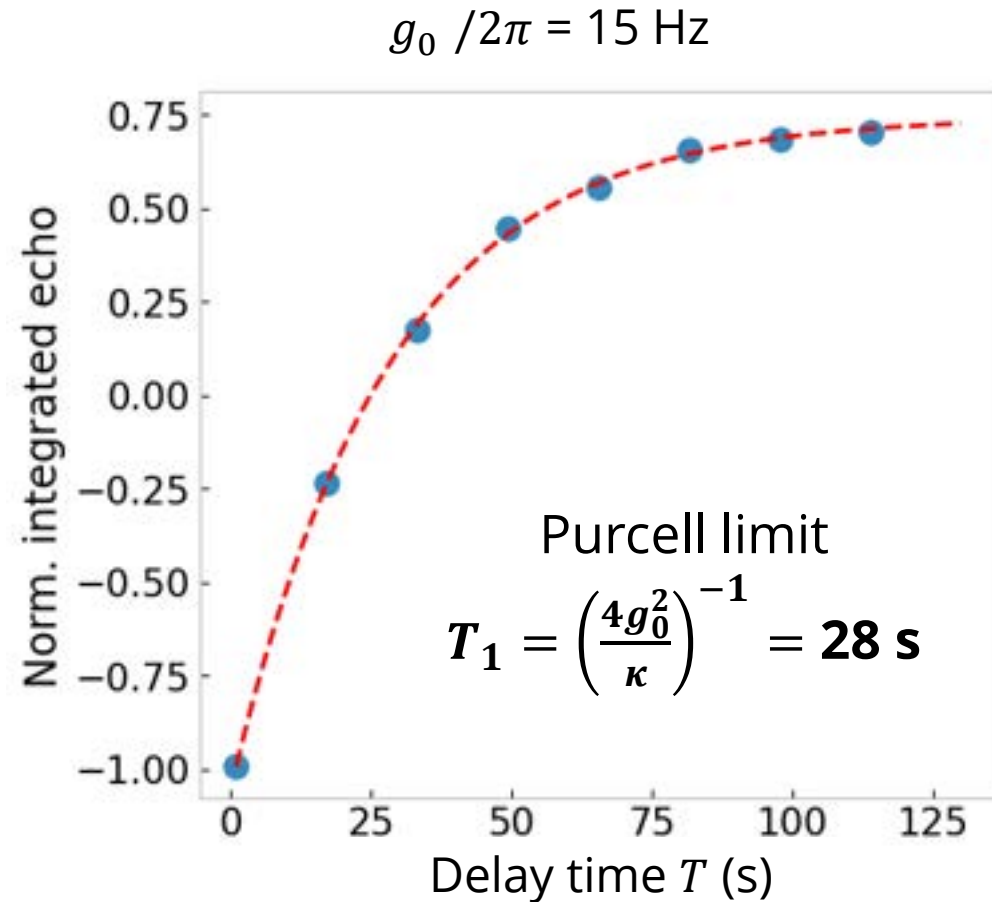
Spin-resonator interaction

Spins create additional losses in resonator



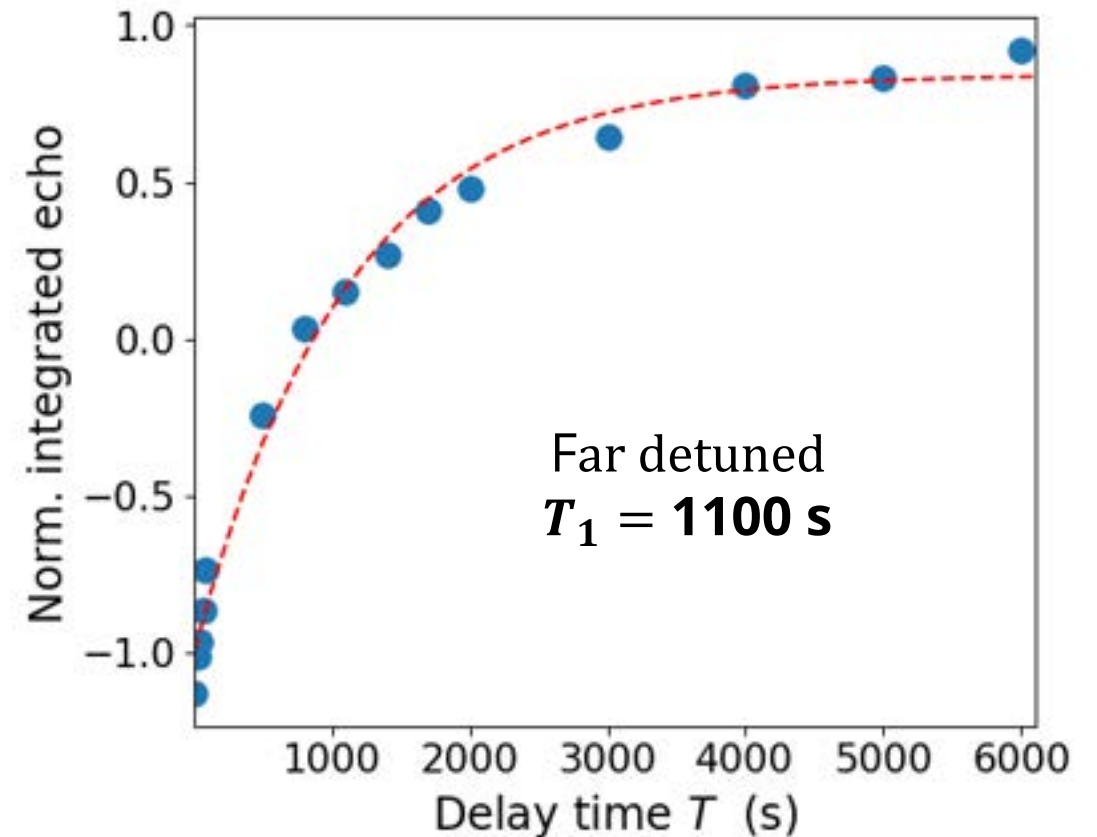
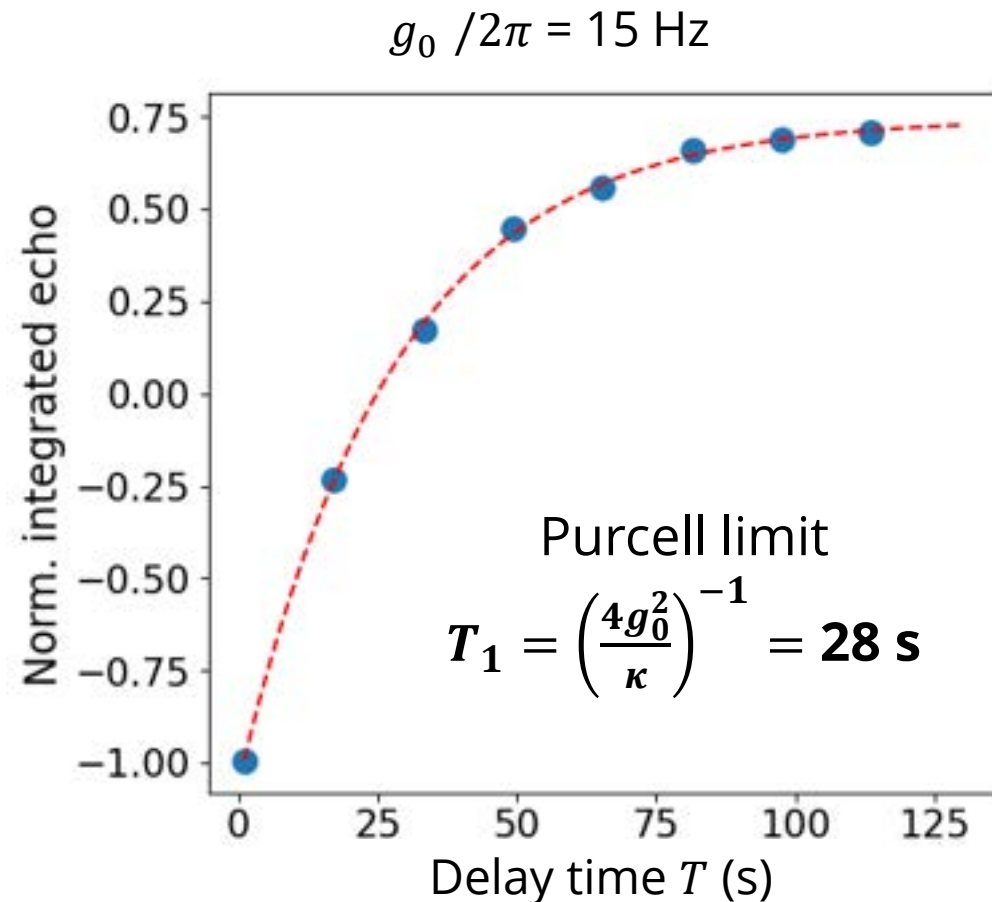
Spin-resonator interaction: Purcell effect

Resonator shortens the spin lifetime



Spin-resonator interaction: Purcell effect

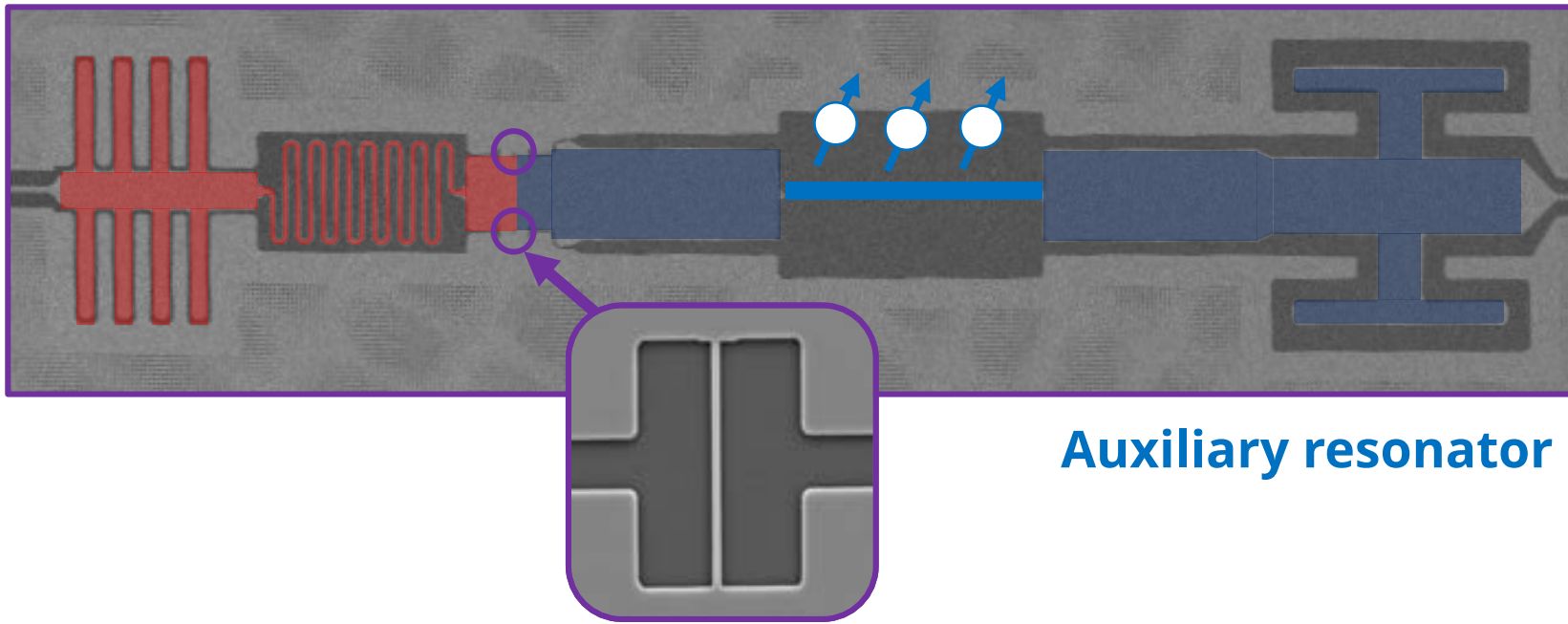
Resonator shortens the spin lifetime and sets the repetition rate of our experiment ...



Device summary

Buffer resonator

Spins : Bismuth donors in silicon

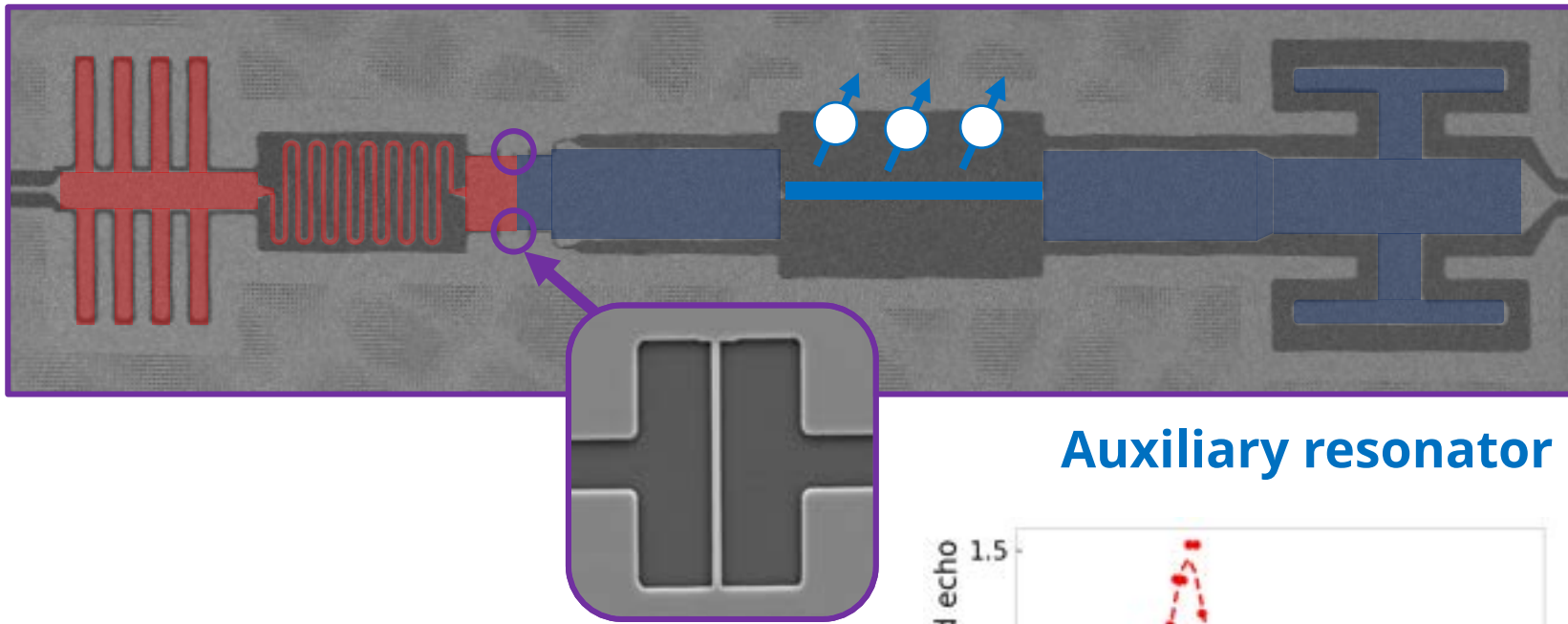


- ✓ Tunable resonator frequency
80 MHz tuning range
3 MHz dynamic tuning
- ✓ Tunable linewidth
From $\kappa_A/2\pi = 165$ kHz to 650 kHz
- ✓ Long spin coherence
450 ms at sweet-spot
- ✓ Reset by the Purcell effect
- Reach unit cooperativity
 $C = 0.1$

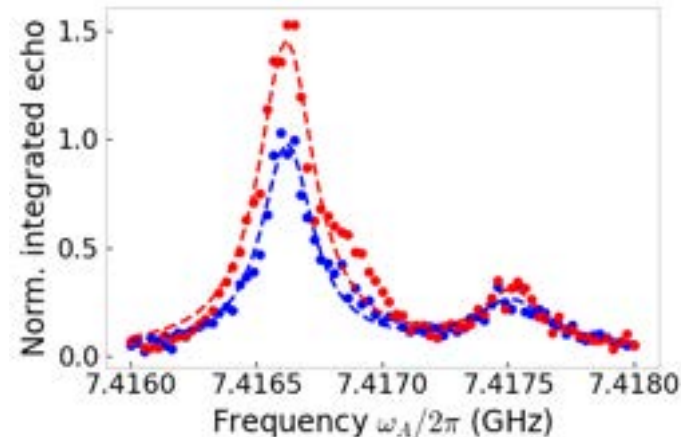
Device summary

Buffer resonator

Spins : Bismuth donors in silicon



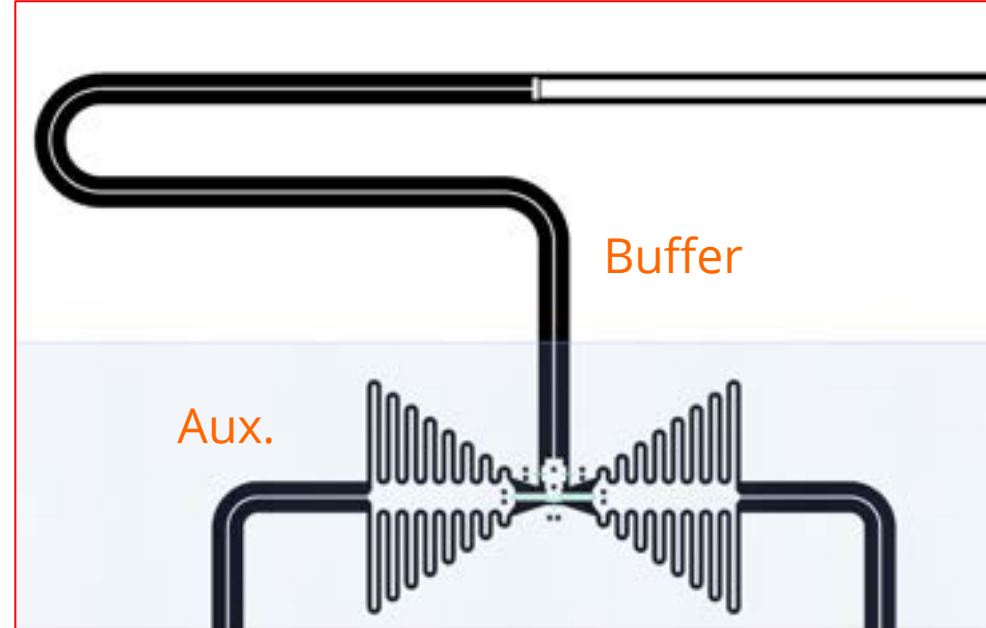
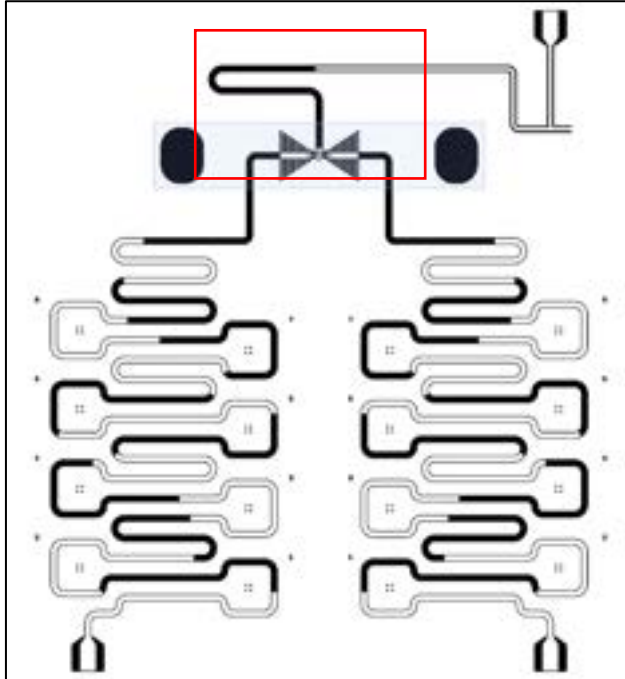
Auxiliary resonator



- ✓ Long spin coherence
450 ms at sweet-spot
- ✓ Tunable resonator frequency
80 MHz tuning range
3 MHz dynamic tuning
- ✓ Tunable linewidth
From $\kappa/2\pi = 165$ kHz to 650 kHz
- Reach unit cooperativity
 $C = 0.1 \rightarrow 0.45$ (in 45 min)

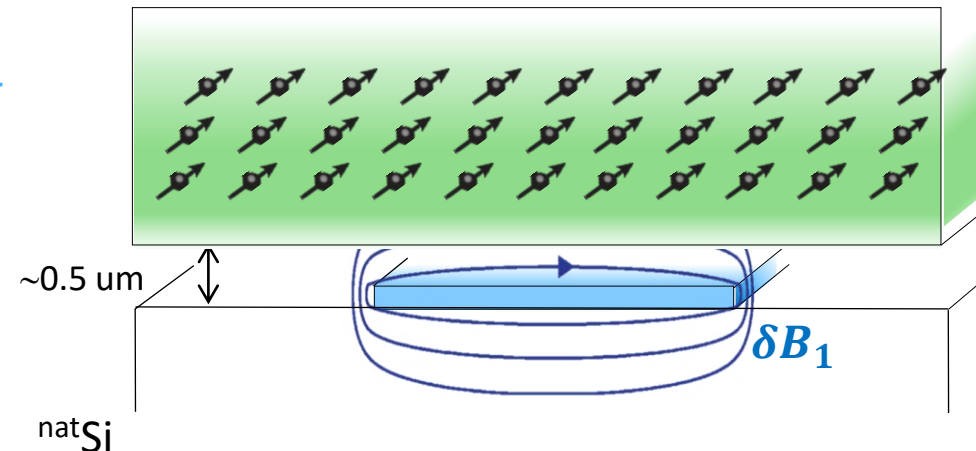
Pespectives : new device

10mm chip



Transition with higher
matrix element

Smaller spacing



- Larger coupling to spins

- Low-loss microwave access

- Low-loss resonators

- Predict $C=1.5$ with $T_{\text{rep}} = 5\text{s}$

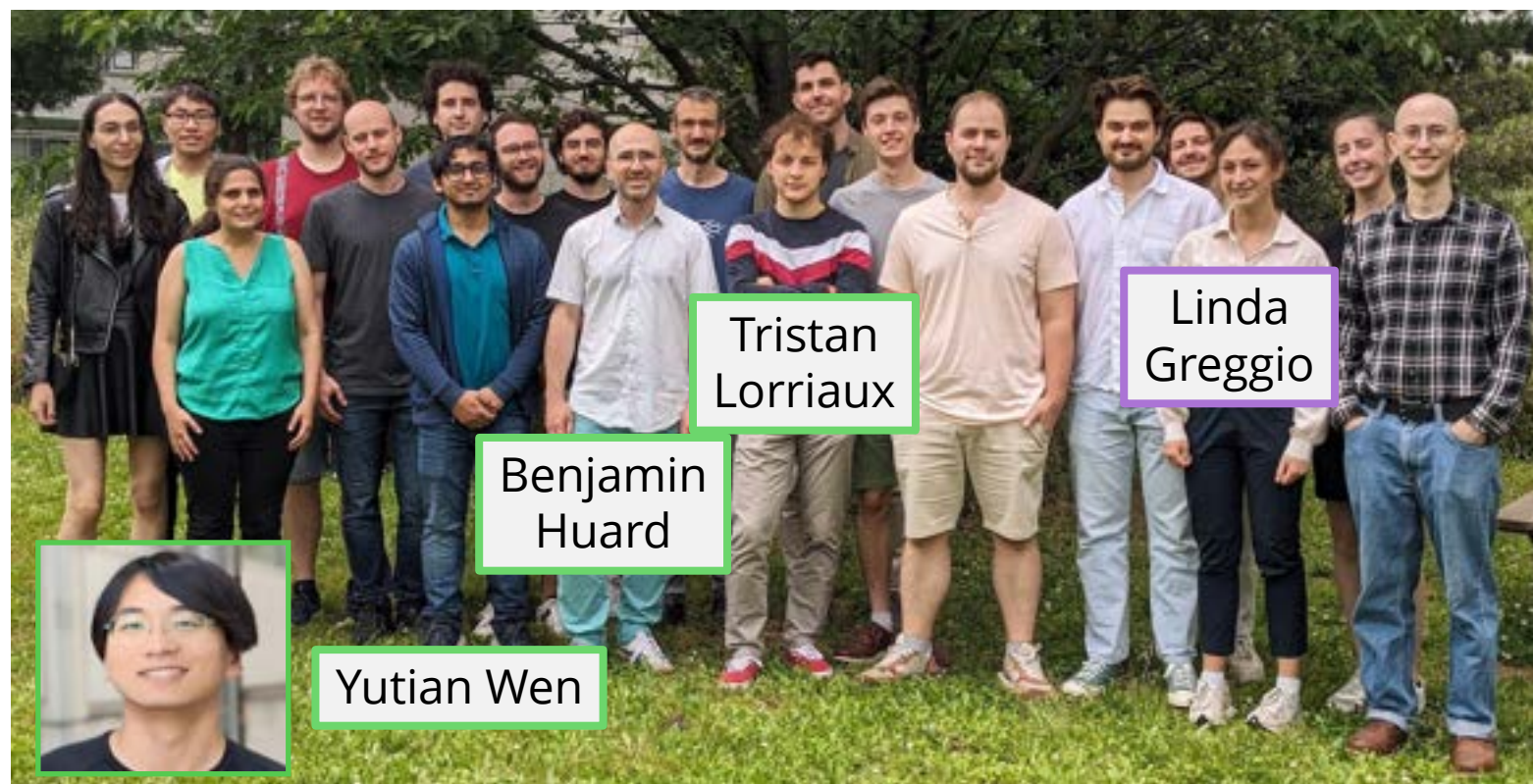
Inhomogeneous linewidth ?

X2 deeper implantation

Larger zpf for the magnetic field

Acknowledgments

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CEA-Saclay

